



凝聚态物理—北京大学论坛



二维狄拉克材料的可控生长 与光电性质研究

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北京大学 化学与分子工程学院

2013-09-26



北京大学

致谢

经费:



国家重点基础研究发展计划

课题组:



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沈志勋 教授
张首晟 教授
崔屹 副教授

Research Interests:

Synthesis/characterization

- graphene
- chalcogenide (topological insulator)
- heterostructure

Nano Lett. 7(1), 199 (2007)
Nano Lett. 7(12), 3734 (2007)
Nano Lett. 8(5), 1511 (2008)
Nano Lett. 9(3), 1265 (2009)
Nano Lett. 10(3), 2870 (2010)
Nano Lett. 10(6), 2245 (2010)
Nano Lett. 11(3), 1106 (2011)
Chem. Mater. 21(2), 247 (2009)
J. Am. Chem. Soc. 129, 34 (2007)
J. Am. Chem. Soc. 131, 7973 (2009)
J. Am. Chem. Soc. 134, 6132 (2012)
J. Am. Chem. Soc. 135, 13274 (2013)
Acc. Chem. Res. (2013)

2D layered materials

Band structure engineering

- chemical modification
- doping
- intercalation chemistry

Nano Res. 2, 327 (2009)
ACS Nano 5, 5957 (2011)
Small 9, 1348 (2013)
Small 9, 1134 (2013)
Small 9, 1388 (2013)
Small 9, 1316 (2013)
Nature Commun. 4, 1443 (2013)

Novel device

- nanoelectronics
- optoelectronics

Nature Materials 9, 225 (2010)
Nature Chemistry 4, 281 (2012)
Nature Commun. 3, 1280 (2012)
J. Am. Chem. Soc. 135, 10926 (2013)
Adv Mater. (2013)

“Star Nanomaterials” in the last 30 years

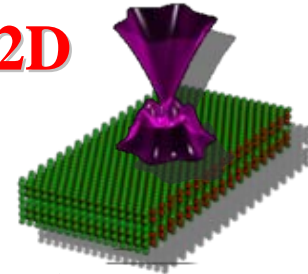
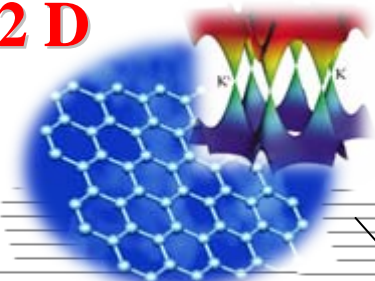
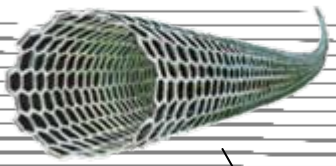
Dimensionality evolution



1 D

2 D

2D

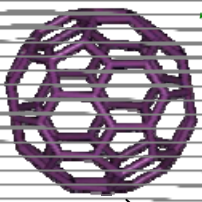


Topological insulator
 Kane, *PRL* 95, 146802 (2005)
 Zhang, *Science* 314,1757 (2006)
 Moore, *PRB* 75, 121306 (2007)

Graphene, 2004
 (Manchester Univ.)
 A. Geim, *Science*, 306, 666 (2004)

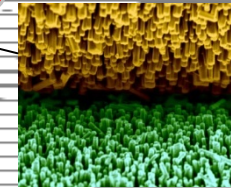
0 D

Carbon nanotube, 1991 (NEC)
 S. Iijima, *Nature*, 354, 56 (1991)



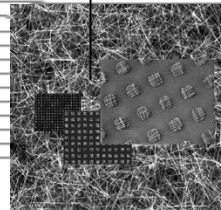
Fullerene, 1985 (Rice Univ.)
 Kroto, *Nature*, 318, 162 (1985)

1 D

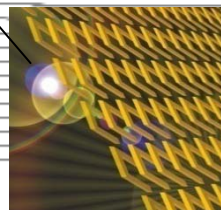


ZnO nanowire, 2001
 Z. L. Wang, *Science* 291, 1947 (2001)

1 D

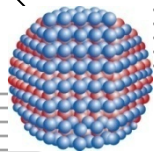


Si & Ge Nanowires,
 C.M. Lieber, *Science* 279, 208 (1998)



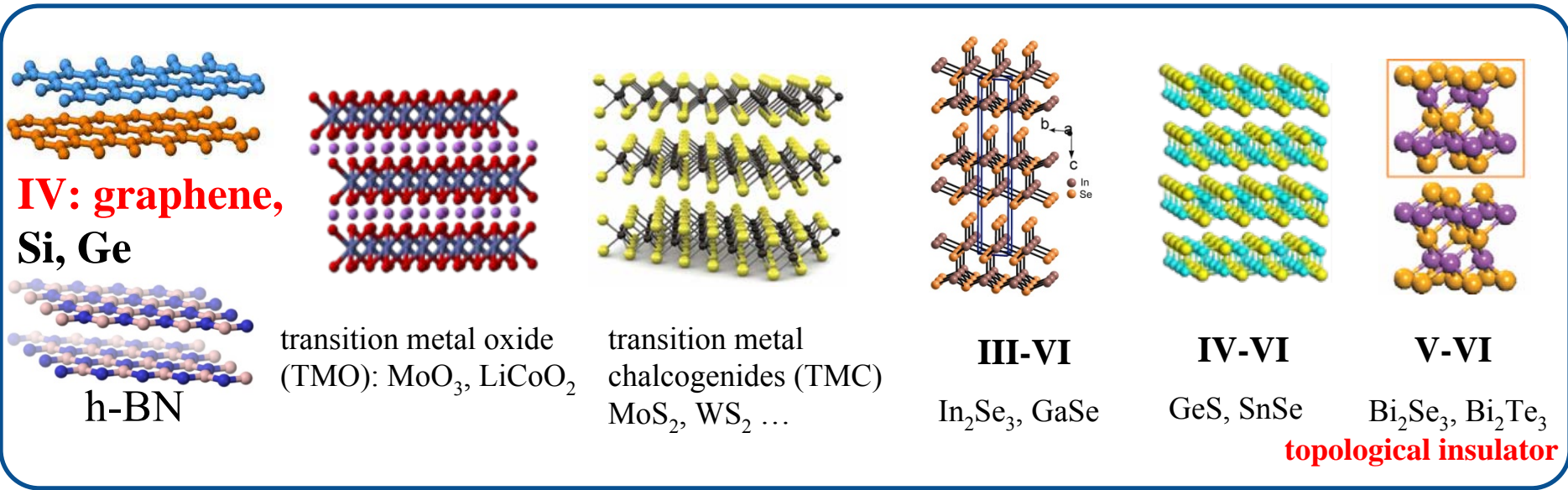
Metamaterial, 2000
 (UCSD, USA)
 D. R. Smith, *PRL*, 84, 418495 (2000)

0 D

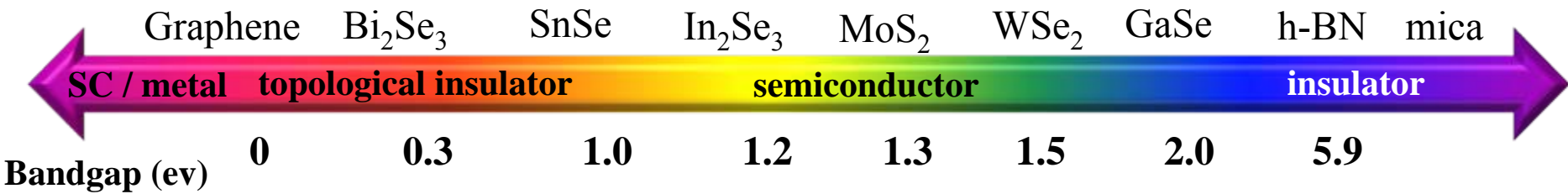


Quantum dot, 1981
 (Vavilov State Opt. Ins.)
 A. Ekimov, *JETP Lett.*, 34, 345 (1981)

Two-Dimensional Crystal Family

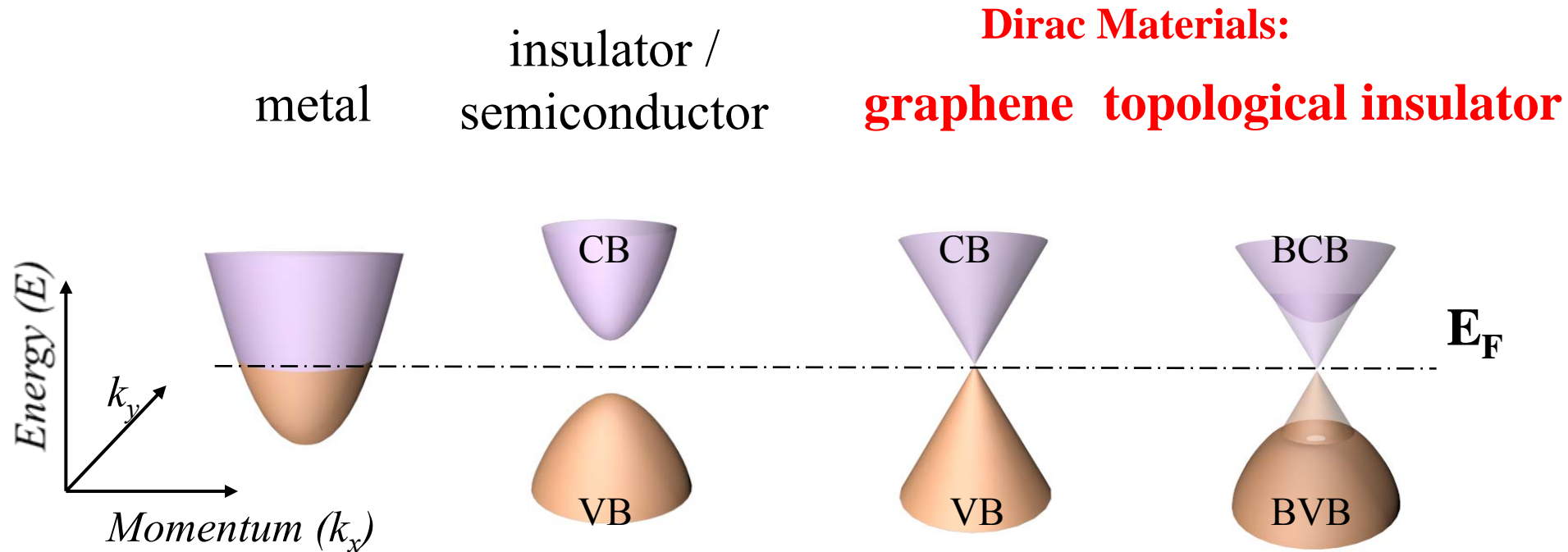


- Layered and anisotropic structure; strong in-plane bonding; weak interlayer van der Waals bonding
- Large variety of electronic properties



- Properties of 2D crystals are very different from their 3D counterparts

Electronic band structures



$$E = \hbar^2 k^2 / 2m^*$$

$$E \propto k^2$$

Parabolic type band structure

$$E_{K(K')} = \pm \eta v_F |k|$$

$$E \propto k$$

Dirac cone type:

linear energy-momentum “relativistic” dispersion described by the massless Dirac Hamiltonian

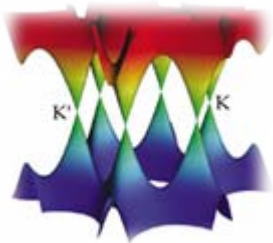
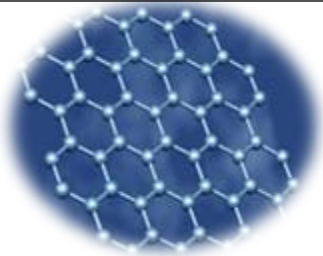
2D Dirac Materials

狄拉克材料 (Dirac 费米子系统)
Dirac 锥形能带结构: 能量-动量线性关系

Graphene

Layered structure

Dirac cone

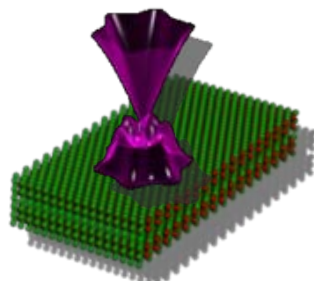


Geim, et al., *Science* 306, 666(2004)

Topological insulator 拓扑绝缘体

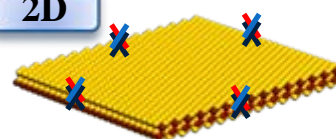
Dirac cone

Electrons live on the surfaces

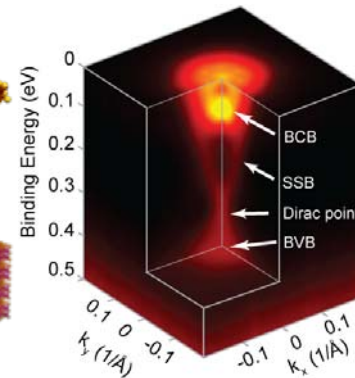
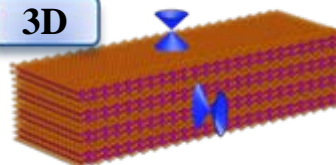


Bi_2Se_3 , Bi_2Te_3 , Sb_2Te_3

2D



3D



“Locking” of current & spin

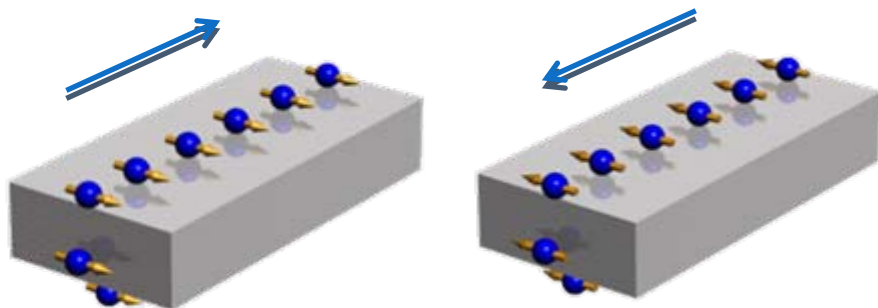
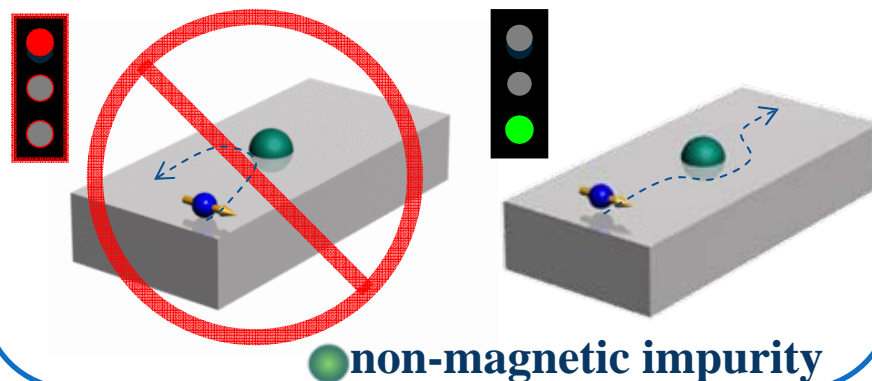


Image courtesy Y. L. Chen

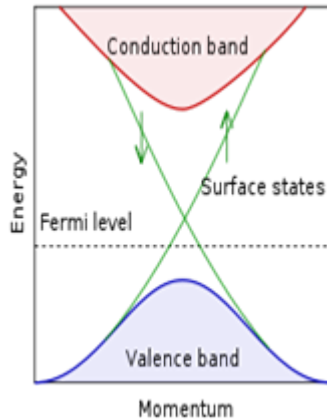
No back-scattering rule



● non-magnetic impurity

Robust, dissipationless spin currents

Topological Insulators and Their Applications



a new quantum material with insulating bulk and gapless Dirac surface state

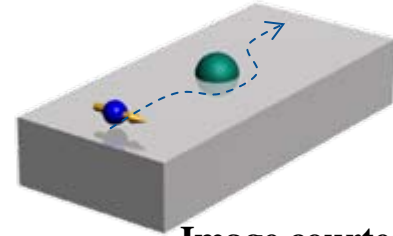
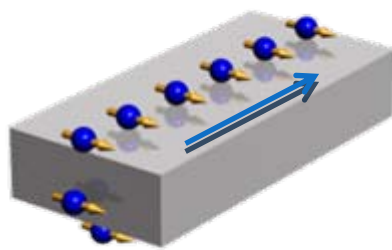
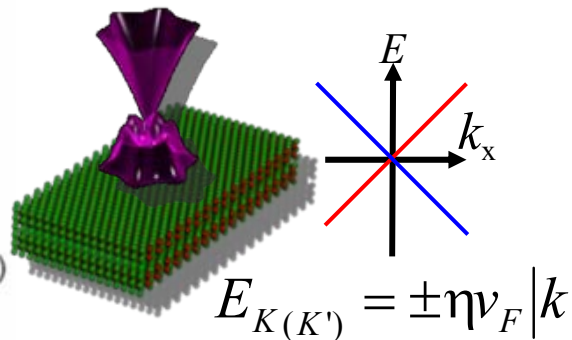
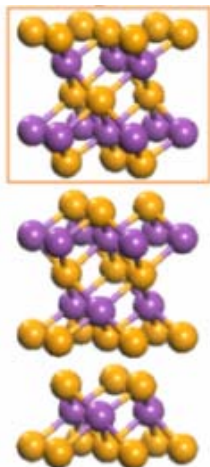


Image courtesy Y. L. Chen

“Locking” of current & spin No back-scattering rule

Robust, dissipationless spin current generated at surfaces



3D TI:

$\text{Bi}_x\text{Sb}_{1-x}$

$\text{Bi}_2\text{Se}_3, \text{Bi}_2\text{Te}_3, \text{Sb}_2\text{Te}_3$

$\text{Bi}_2\text{Se}_2\text{Te}, \text{Bi}_2\text{SeTe}_2, (\text{Bi}_x\text{Sb}_{1-x})_2\text{Te}_3$

$\text{TlBiTe}_2, \text{TlBiSe}_2, \text{TlBiS}_2, \text{TlSbTe}_2, \text{TlSbSe}_2$

$\text{LuPtSb}, \text{LuPdBi}, \text{YPtBi}, \text{CePtBi}, \text{LaPtBi}$

.....

(layered crystal structure) (Dirac band structure)

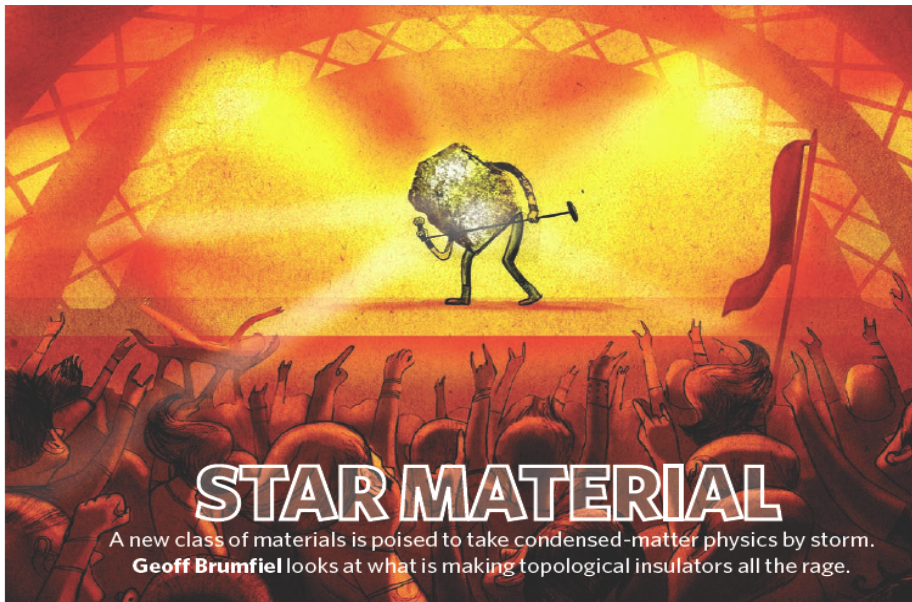
Topological Insulators and Their Applications

- **Fundamental:** quantum anomalous Hall effect, Majorana fermions ...
- **Applications:** information technology, energy, catalysis ...

topological insulator: star material

NEWS FEATURE

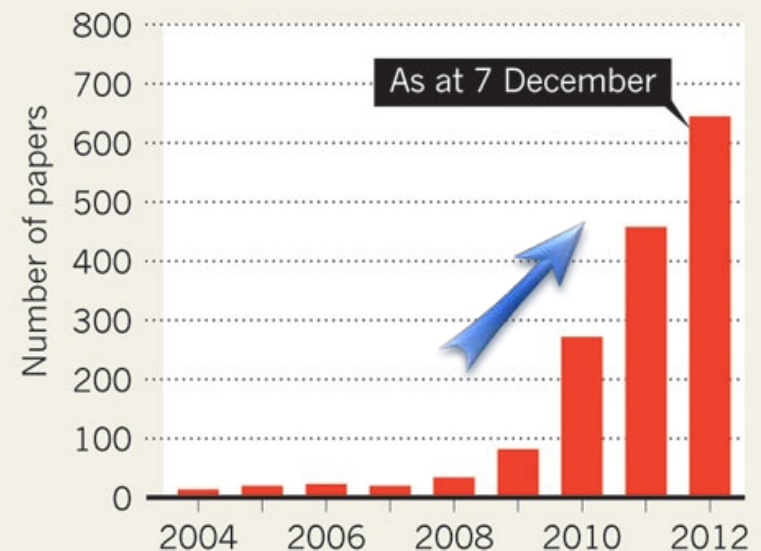
NATURE | Vol 466 | 15 July 2010



Nature 2010, 466, 15 July

CHARGING UP

The number of papers published on topological insulators has grown rapidly over the past few years.



Nature 2012, 492, 165 (13 Dec.)

2D Dirac Material — Calling all chemists

Nature Nanotechnology 3, 10 - 11 (2008)

GRAPHENE

Calling all chemists

Rod Ruoff

is in the Department of Mechanical Engineering,
University of Texas at Austin, Austin,
Texas 78712, USA.

nature
chemistry

PERSPECTIVE

PUBLISHED ONLINE: 24 OCTOBER 2011 | DOI: 10.1038/NCHEM.1171

Yi Cui*, Nature Chemistry 2011, 3, 845

Opportunities in chemistry and materials science
for topological insulators and their nanostructures

TOPOLOGICAL INSULATORS

Chemists join in

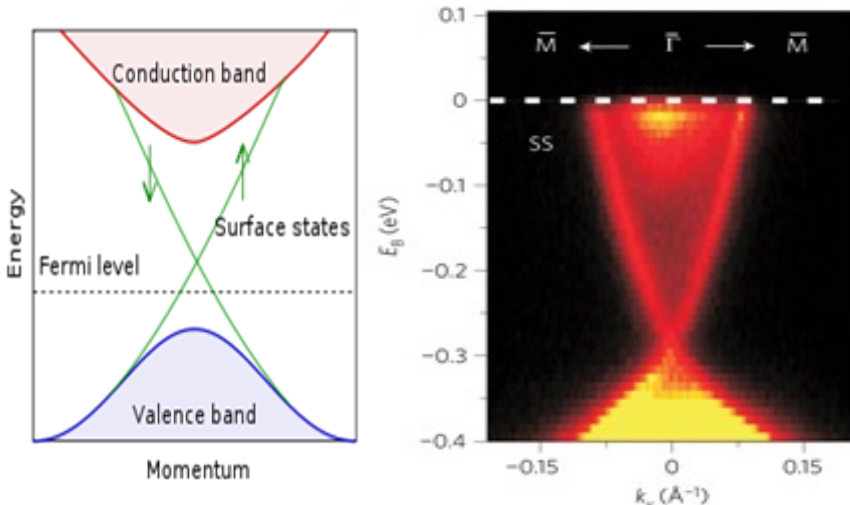
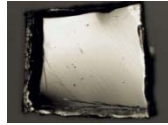
Topological insulators have generated much interest in condensed-matter physics. The synthesis and characterization of $\text{Bi}_{14}\text{Rh}_3\text{I}_9$, a so-called weak topological insulator, demonstrates that chemists also have much to offer to the field.

Robert J. Cava

Nature Materials | VOL 12 | MAY 2013

Our Approach to Study Topological Insulators

Bi₂Se₃ bulk single crystal



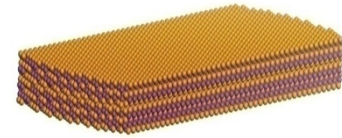
Y. Xia et al., *Nature Physics* 5, 398 (2009)

Surface states are overwhelmed by unwanted bulk carriers.

Issues:

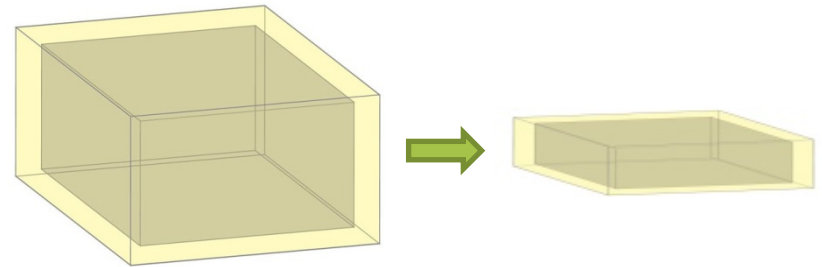
- Surface state vs. bulk state
- High-quality materials
- Transport

2D nanostructures



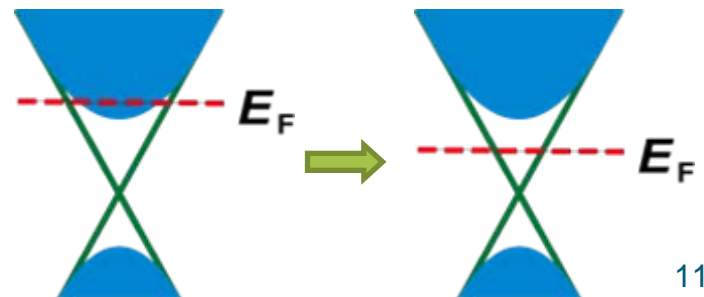
nanoribbon, nanoplate, nanosheet,...

- Large surface-to-volume ratio



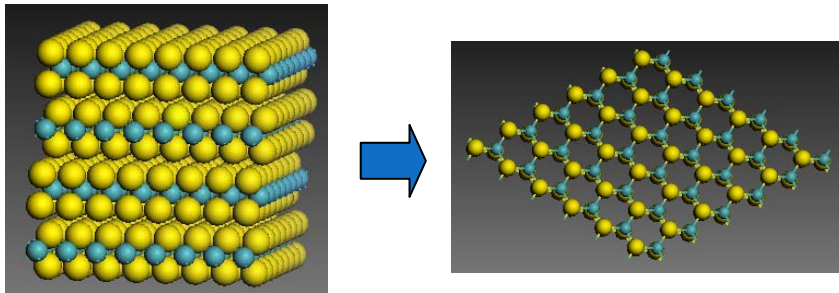
- Excellent transport geometry

- Highly tunable chemical potential (doping, gating)



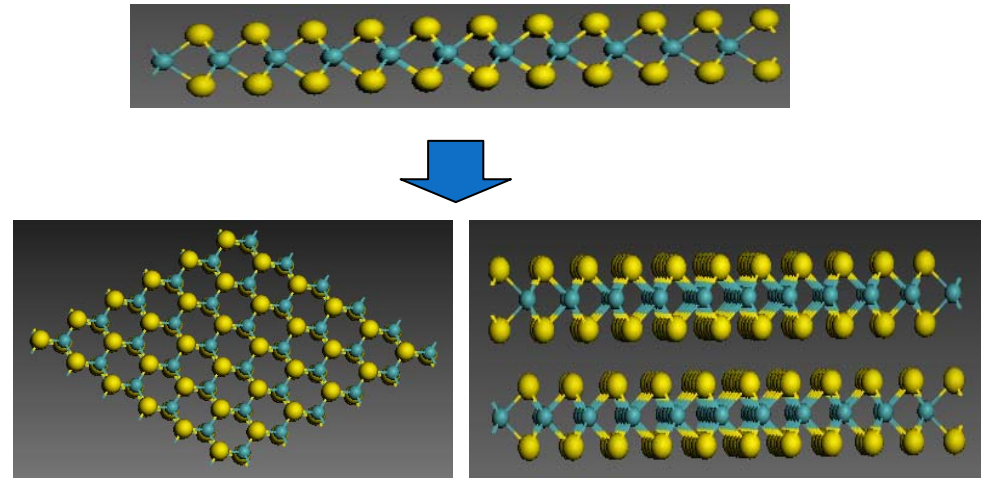
Production of 2D Layered Crystals

Top-down

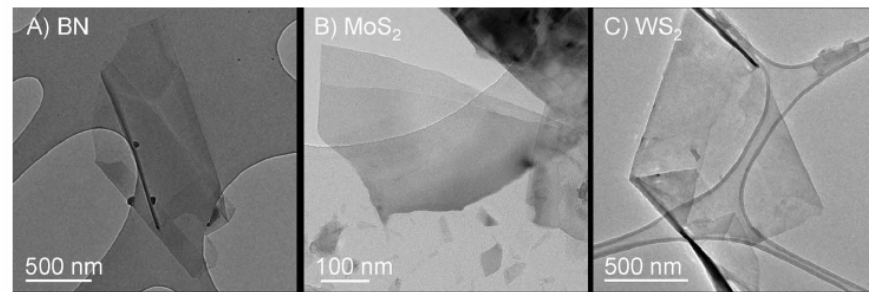


- **Micromechanical exfoliation**
- **Liquid-phase exfoliation**
(ultrasonic, ion/molecule insertion)

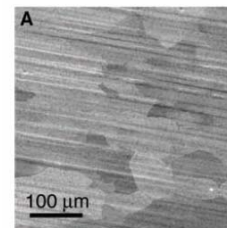
Bottom-up



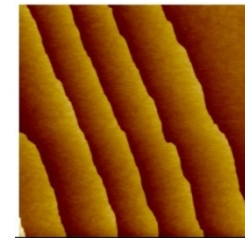
- **Liquid-phase synthesis**
- **Vapor-phase synthesis**



J. N. Coleman, et al. *Science* 331, 568 (2011)



CVD of graphene



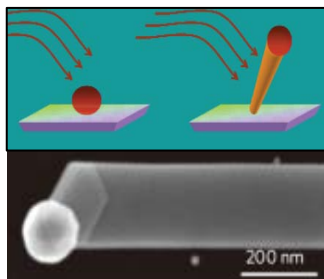
MBE of Bi_2Se_3

R. Ruoff, *Science* (2009) QK Xue, et al. *Nat. Phys.* (2010)



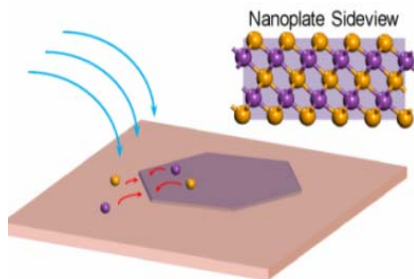
Dirac 2D Crystals and their novel optoelectronic devices

**VLS growth:
TI nanoribbon**



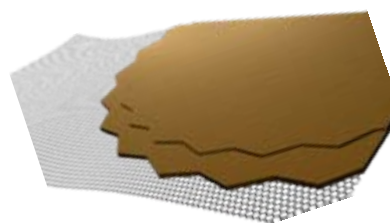
*arXiv:0908.3314 (2009);
Nano Lett. 2010, 10, 329*

**VS growth:
TI nanoplate**

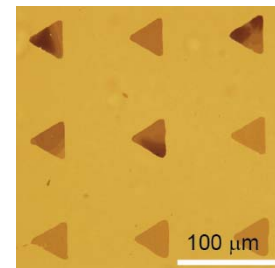


Nano Lett. 2010, 10, 2245

**van der Waals epitaxy: Selective-area VDWE:
Nanosheet/thin film
2D ordered array**



*Nano Lett. 2010, 10, 2870;
Nano Lett. 2011, 11, 1106*



*JACS 2012, 134, 6132
JACS 2013, 135, 13274*

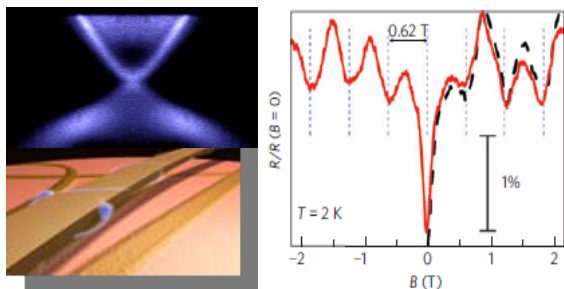
2009

2010

2011

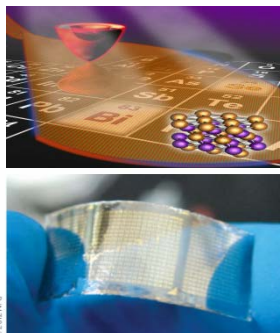
2012

**AB effect of surface state by
quantum transport**



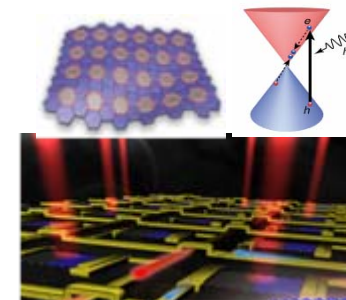
Nature Mater. 2010, 9, 225

**TI nanostructure for
flexible transparent electrode**



*Nature Chem. 2012, 4, 281
Adv. Mater. 2013*

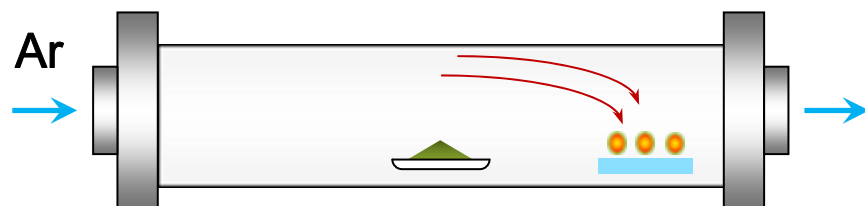
**Dirac materials chemistry and
PN junction for optoelectronics**



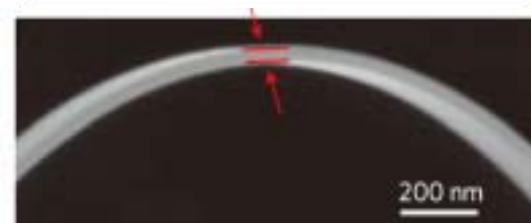
*Nature Comm. 2012, 3, 1038
Nature Comm. 2013, 4, 1443
JACS 2013, 135, 10926*

Growth of 1D/2D Bi_2Se_3 Crystals

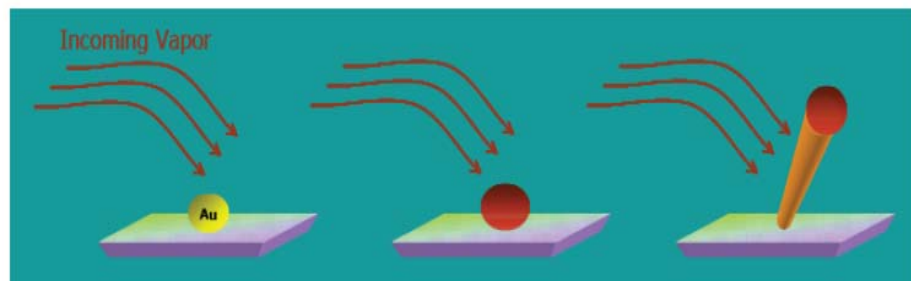
• Vapor-liquid-solid (VLS) growth of nanoribbon



vapor deposition system



Thickness range: ~25 -100nm



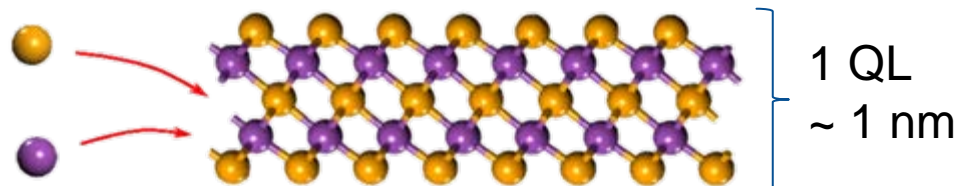
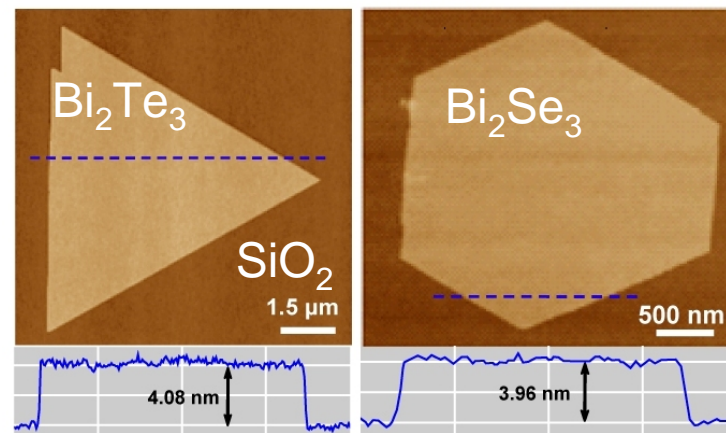
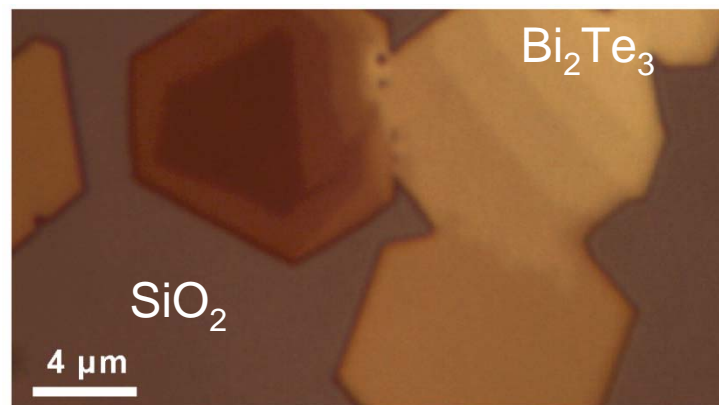
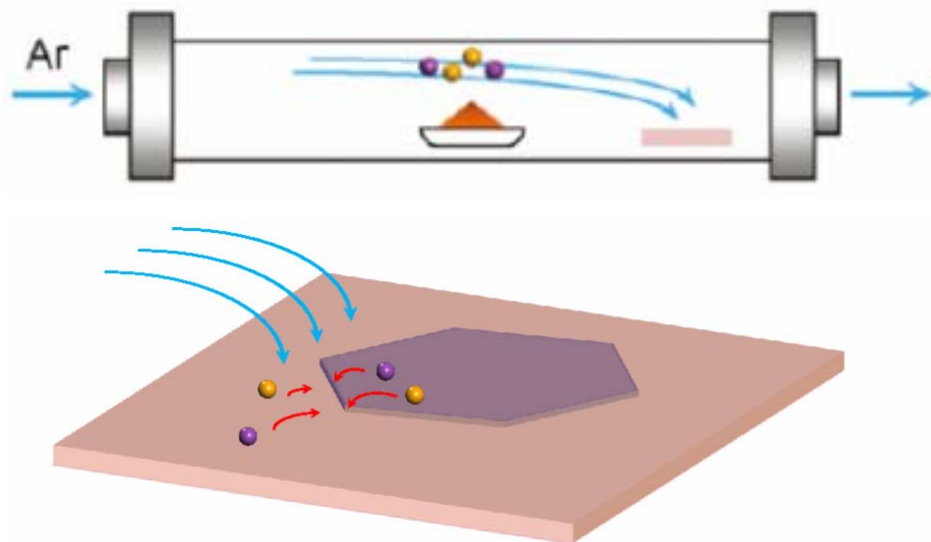
Layered single-crystalline Bi_2Se_3 nanoribbons are synthesized via a gold-catalyzed vapor-liquid-solid growth.

H. Peng, K. Lai, Y. Cui, et al., arXiv:0908.3314 (2009)

Nature Materials 9, 225 (2010)

Growth of 2D Crystals

• Vapor-solid (VS) growth of nanoplate

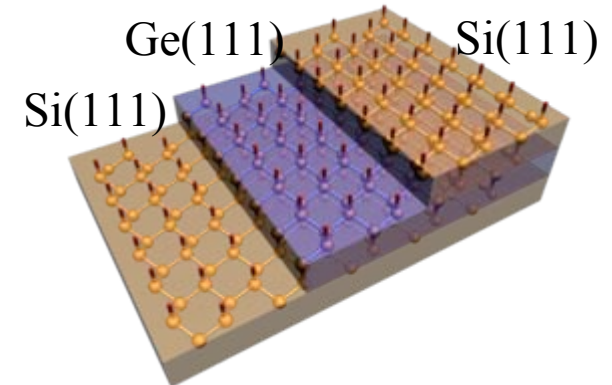
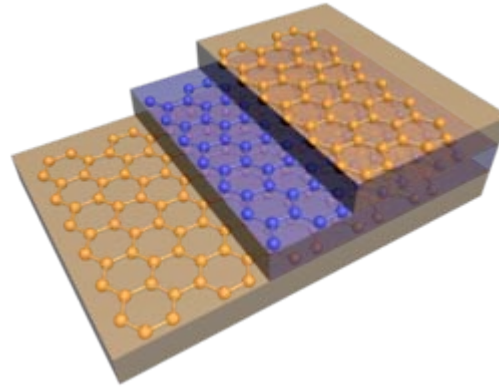
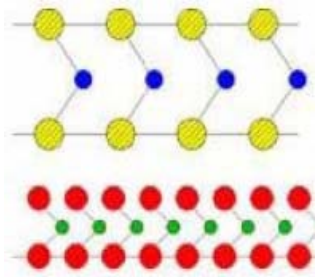


Thickness Range: $\sim 3\ \text{nm}$ to $15\ \text{nm}$

Controlled Growth of 2D Crystals

• van der Waals (VDW) epitaxy

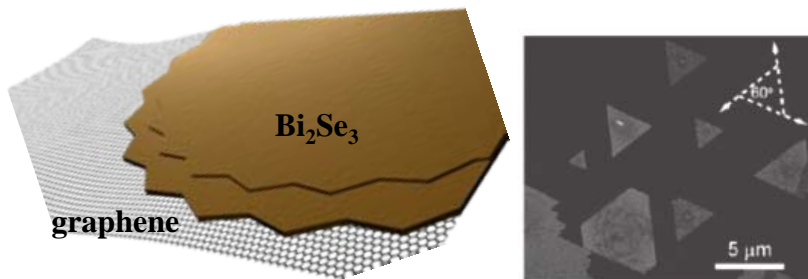
Conventional epitaxy



Koma, A. *Thin Solid Films* 216, 72 (1992)

Lattice matching condition is drastically relaxed

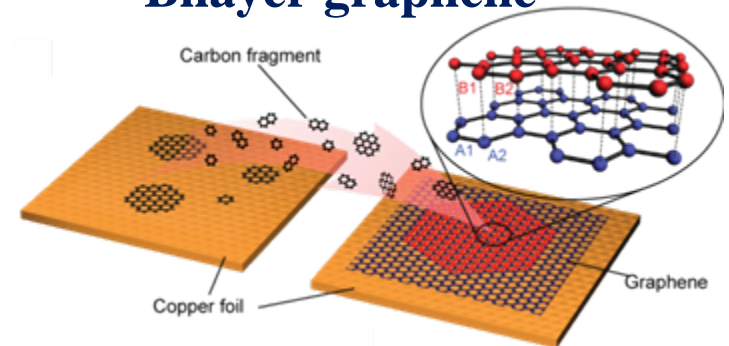
$\text{Bi}_2\text{X}_3/\text{graphene}$ 2D structure



W. Dang, H. Peng, Z.F. Liu, et al.,
Nano Lett. 10, 2870 (2010)

Also see QK Xue, et al. *Nat. Phys.* (2010)

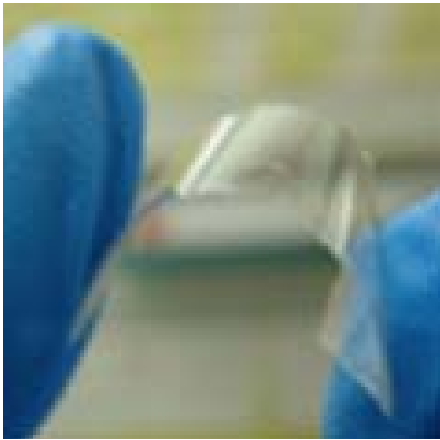
Bilayer graphene



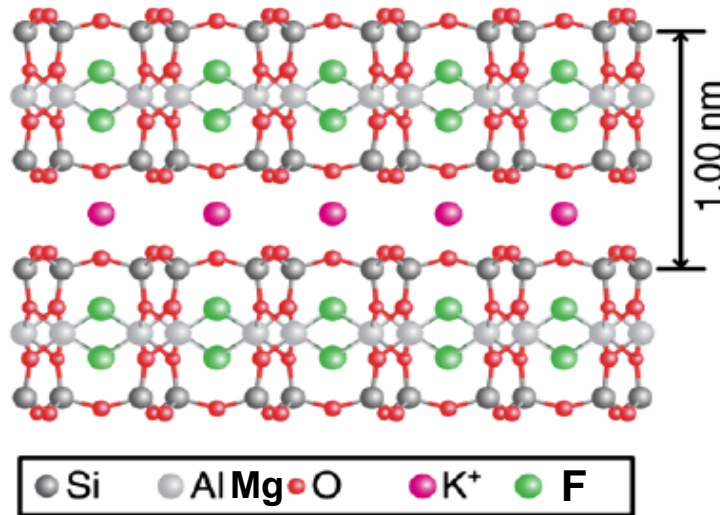
K. Yan, H. Peng, Z. F. Liu, et al.,
Nano Lett. 11, 1106 (2011)

Graphene is a good VDW epitaxy substrate 17

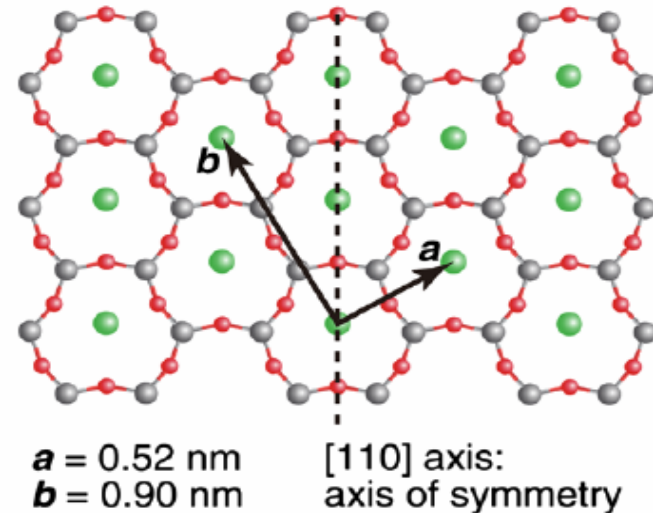
VDW Epitaxy Substrate - Fluorophlogopite Mica



(a) [110] projection



(b) Cleaved surface



T. Fukuma, *Phys. Rev. Lett.* 104, 016101 (2010)

F. Tsui, *Phys. Rev. B* 47, 13648 (1993)

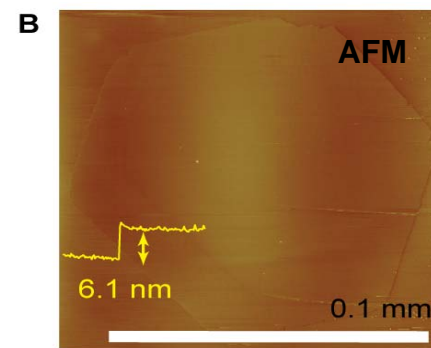
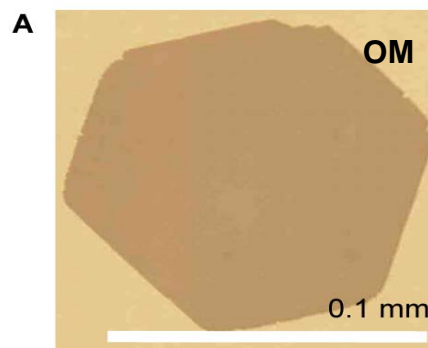
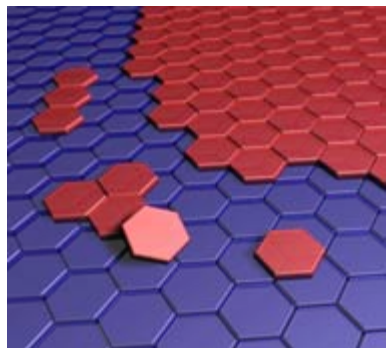
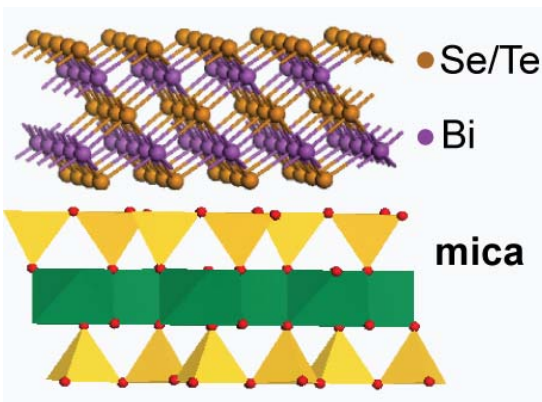
fluorophlogopite mica (氟晶云母)
(2D layered material)

flat, stable, insulating,
transparent, flexible

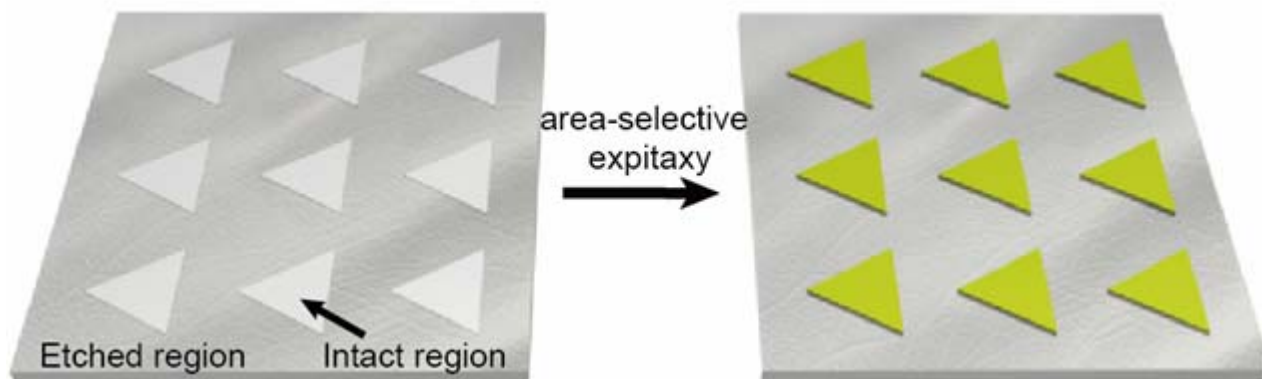
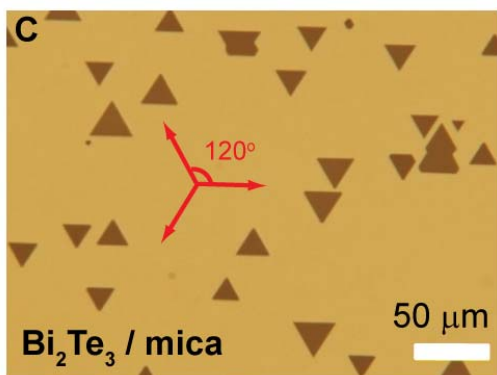
fluorophlogopite $2\text{KMg}_3(\text{AlSi}_3\text{O}_{10})\text{F}_2$
monoclinic structure $C2/m$ space group
 $a = 5.308 \text{ \AA}$, $b = 9.183 \text{ \AA}$, $c = 10.139 \text{ \AA}$, $\beta = 100.07^\circ$
pseudo-hexagonal Z_2O_5 sheets ($Z = \text{Si}$ and Al)

Excellent VDW epitaxy substrate

Position and orientation controlled growth

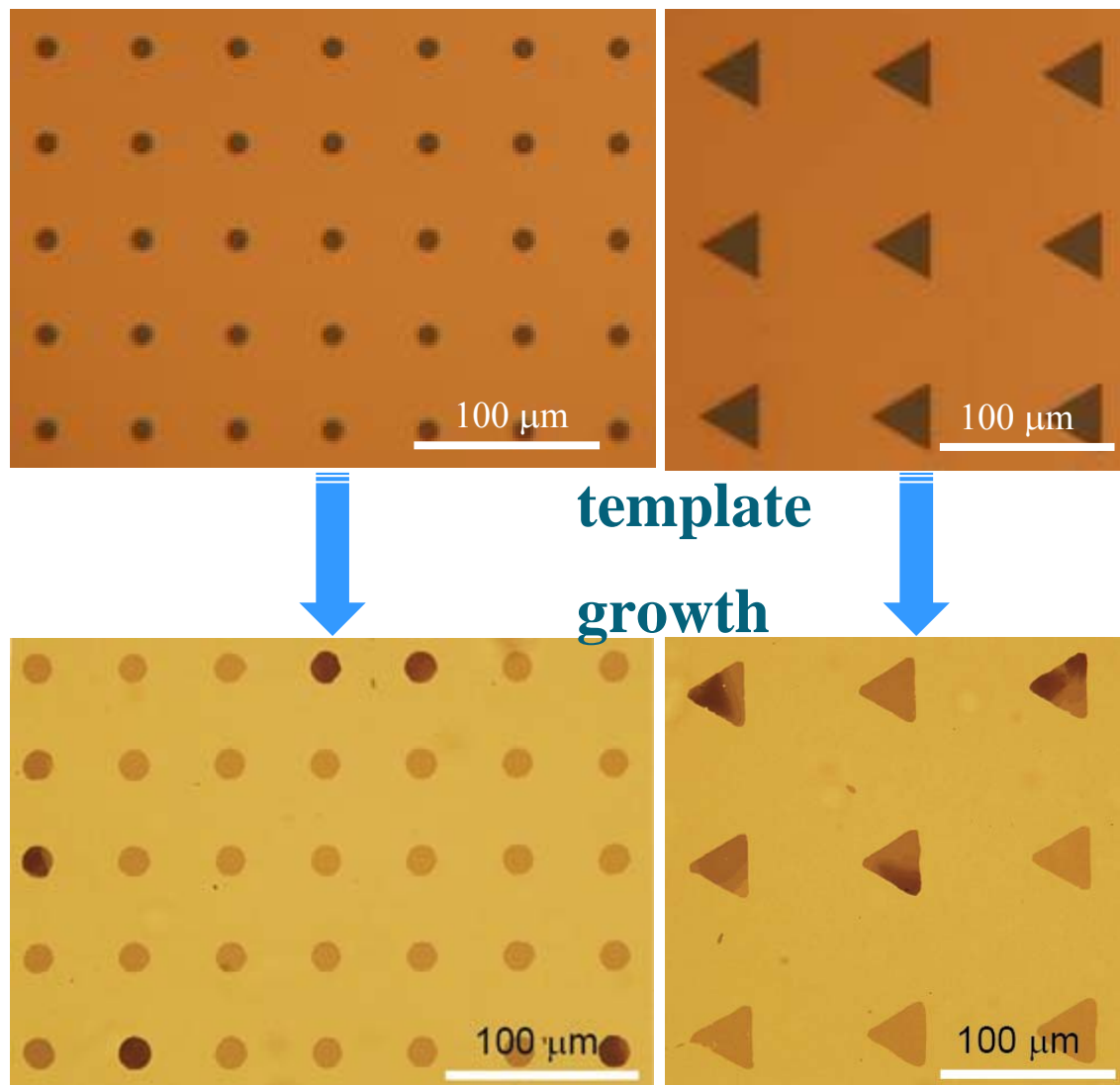


Epitaxy substrate—layered mica (cheap, flat, stable, insulating, transparent, flexible)

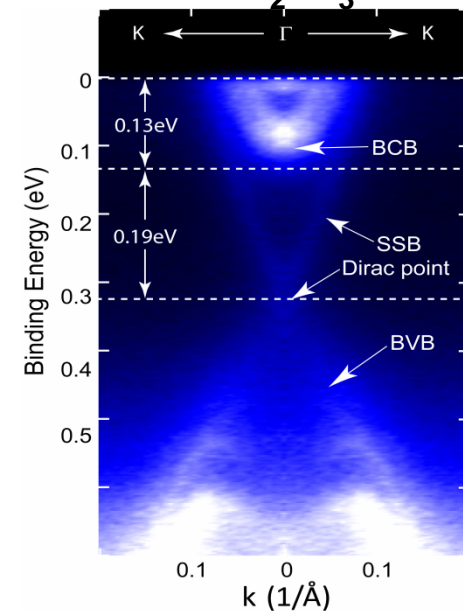


Li, Cao, Zheng, Chen, Peng*, Liu*, *et al.*, *J. Am. Chem. Soc.* 2012, 134, 6132. Highlight in *C&EN*

Position and orientation controlled growth of 2D Bi_2Se_3

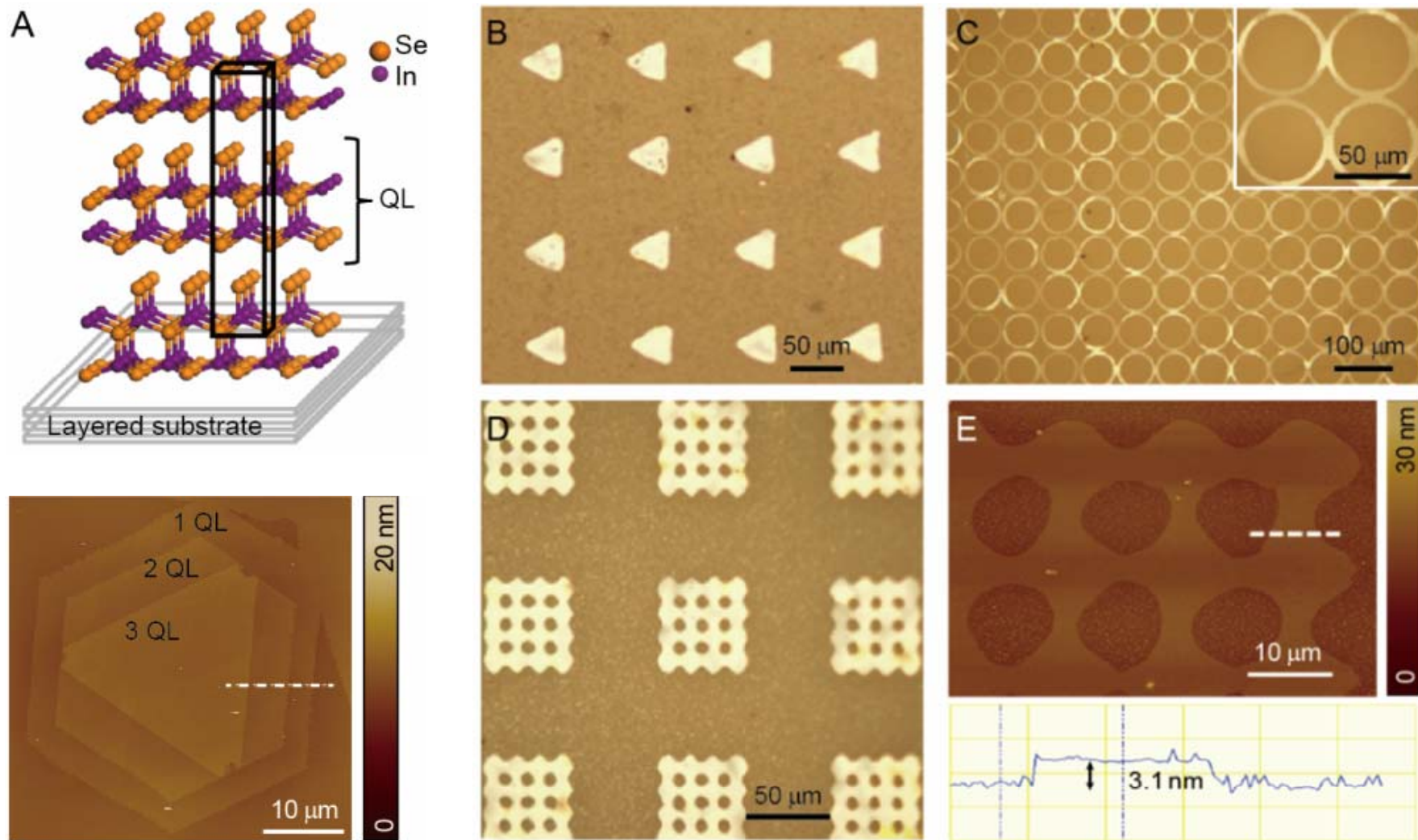


ARPES of Bi_2Se_3 nanosheet



By Dr. Yulin Chen

Position and orientation controlled growth of 2D In_2Se_3



Min Lin, Hailin Peng*, Z.F. Liu*, et al., *J. Am. Chem. Soc.* 2003, 135, 13274

Research Interests:

Synthesis/characterization

- graphene
- chalcogenide (topological insulator)
- heterostructure

Nano Lett. 7(1), 199 (2007)
Nano Lett. 7(12), 3734 (2007)
Nano Lett. 8(5), 1511 (2008)
Nano Lett. 9(3), 1265 (2009)
Nano Lett. 10(3), 2870 (2010)
Nano Lett. 10(6), 2245 (2010)
Nano Lett. 11(3), 1106 (2011)
Chem. Mater. 21(2), 247 (2009)
J. Am. Chem. Soc. 129, 34 (2007)
J. Am. Chem. Soc. 131, 7973 (2009)
J. Am. Chem. Soc. 134, 6132 (2012)
Acc. Chem. Res. (2013)

2D layered materials

Band structure engineering

- chemical modification
- doping
- intercalation chemistry

Nano Res. 2, 327 (2009)
ACS Nano 5, 5957 (2011)
Small 9, 1348 (2013)
Small 9, 1134 (2013)
Small 9, 1388 (2013)
Small 9, 1316 (2013)
Nature Commun. 4, 1443 (2013)

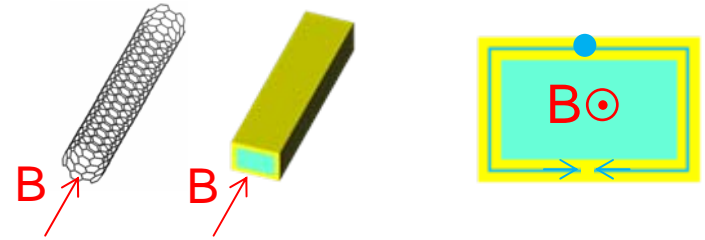
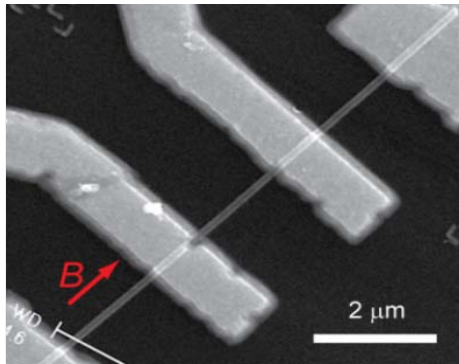
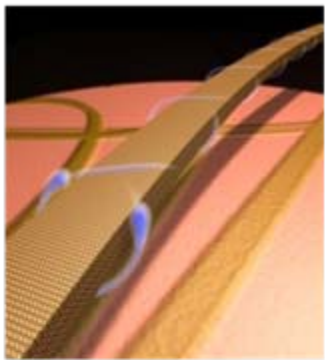
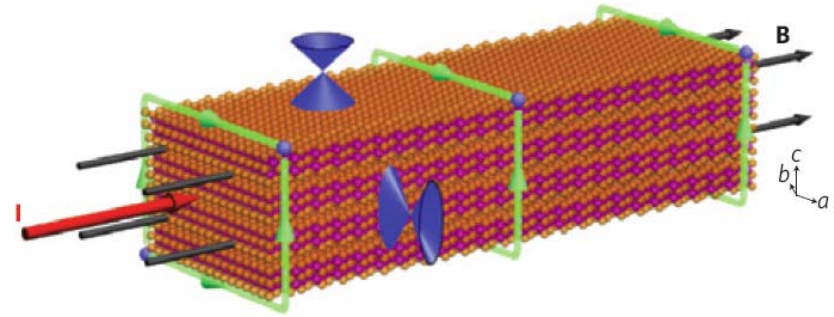
Novel device

- nanoelectronics
- optoelectronics

Nature Materials 9, 225 (2010)
Nature Chemistry 4, 281 (2012)
Nature Commun. 3, 1280 (2012)
J. Am. Chem. Soc. (2013)
Adv Mater. (2013)

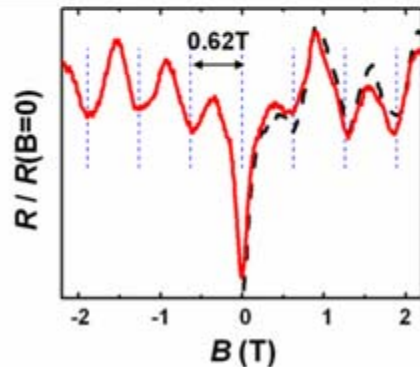
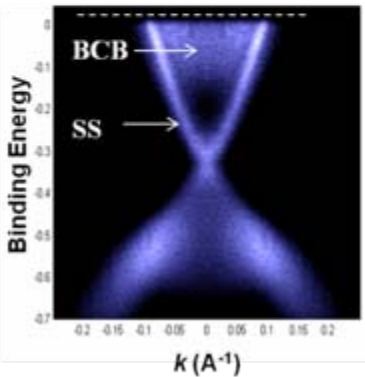
Transport from Surface States of TI (Bi_2Se_3) Nanoribbon

- Periodic magnetoresistance oscillations
- Well-known Aharonov-Bohm (AB) effects
- Fully coverage of 2D coherent electron state on the entire surface of topological insulator



$$\Phi_0 = \Delta B \cdot S = h/e$$

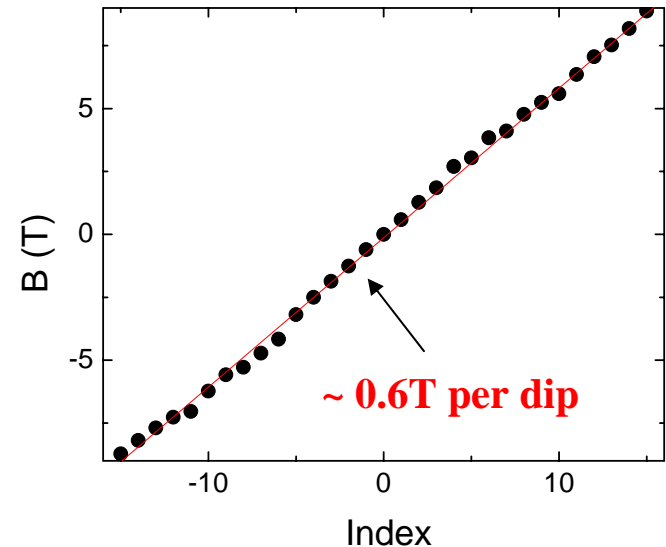
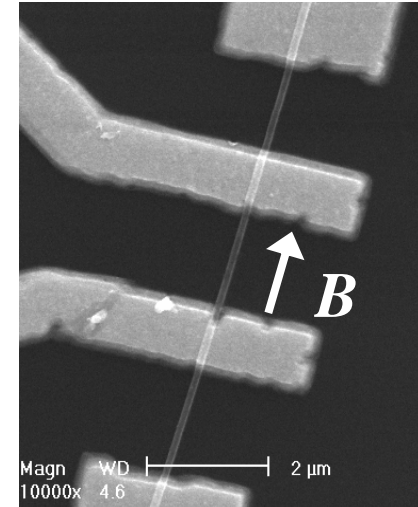
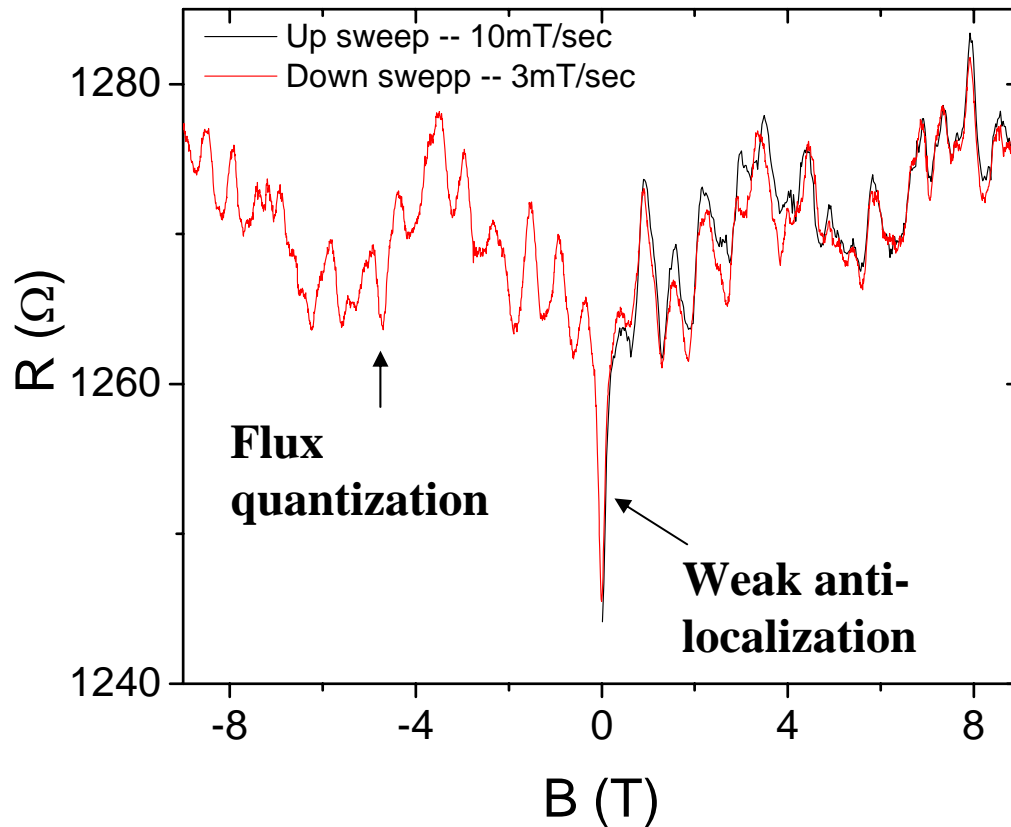
- AB effects observed in ring or tube-like geometry, such as mesoscopic conducting rings, hollow cylinders, tube-like 2DEGs, carbon nanotubes.
- The flux quantization results in an oscillation period of the external magnetic field ΔB . $\Delta B \cdot S = \Phi_0$, where $\Phi_0 = h/e$ is the flux quantum, S the enclosed cross section.



H. Peng, K. Lai, Y. Cui, *et al.*, *Nature Materials* **2010**, *9*, 225. **Times of citation > 200**

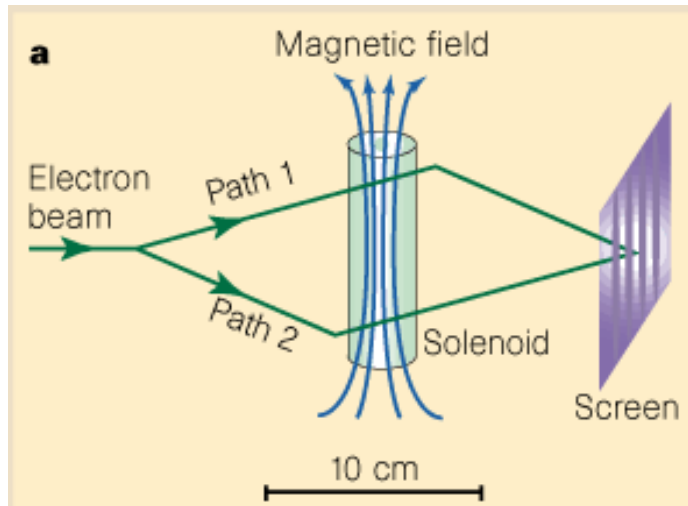
In-plane magnetoresistance in Bi_2Se_3 nanoribbons

Temperature: 2K



- Periodic magnetoresistance oscillations;
- Well-known Aharonov-Bohm effects

Aharonov-Bohm (AB) oscillations



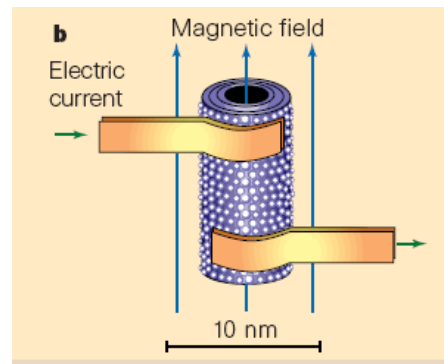
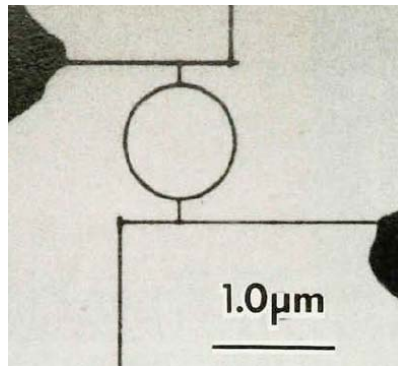
Aharonov-Bohm (AB) effects:

An electron beam, split into two alternative paths, can exhibit interference effects when the beams recombine.

The flux quantization results in an oscillation period of the external magnetic field ΔB .

$\Delta B \cdot S = \Phi_0$, where $\Phi_0 = h/e$ is the flux quantum, S the enclosed cross section.

AB effects have been observed in mesoscopic conducting rings, hollow cylinders, and tube-like 2DEGs

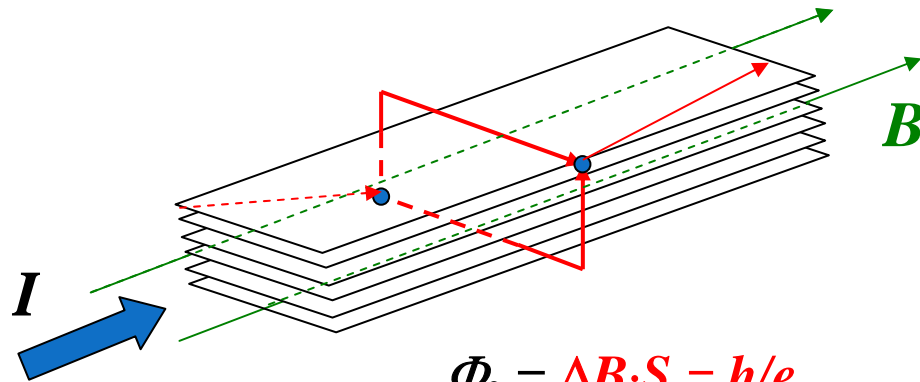


$$\Phi_0 = \Delta B \cdot S; \Phi_0 = h/e$$

Aharonov, Y. & Bohm, D. Phys. Rev. 115, 485 (1959)

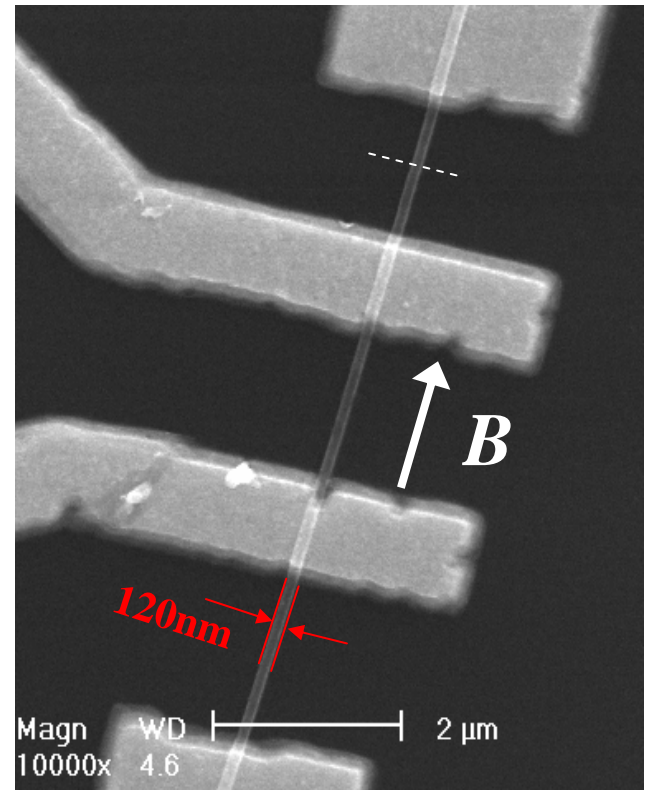
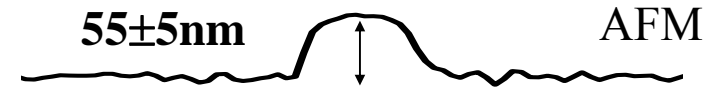
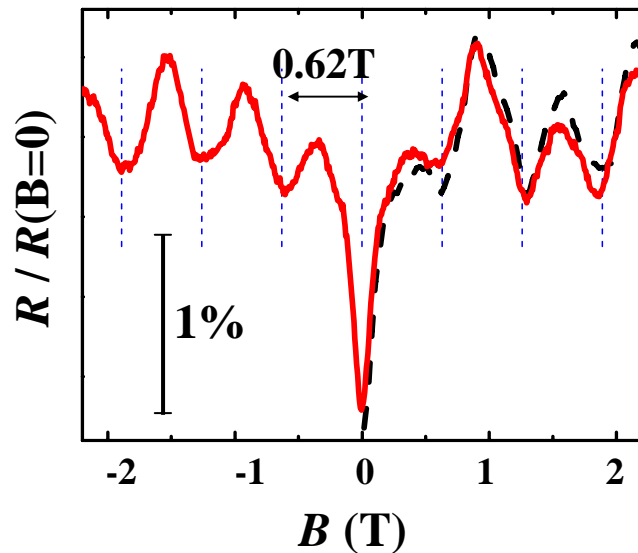
Bachtold, A. Nature 397, 673 (1999)

Aharonov-Bohm oscillation from surface states



$$\Phi_0 = \Delta B \cdot S = h/e$$

Expected AB period: $\Delta B = \Phi_0 / S = 0.63\text{T}$

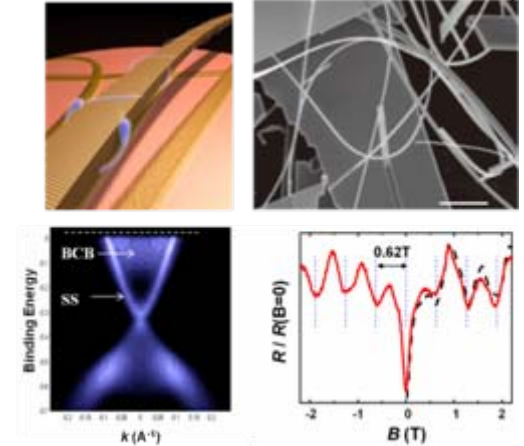
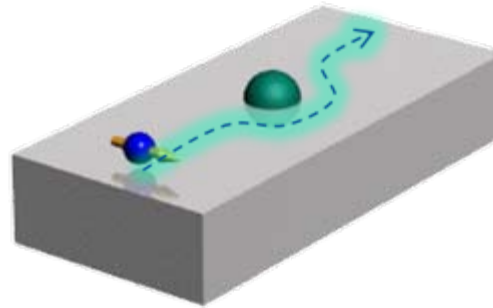
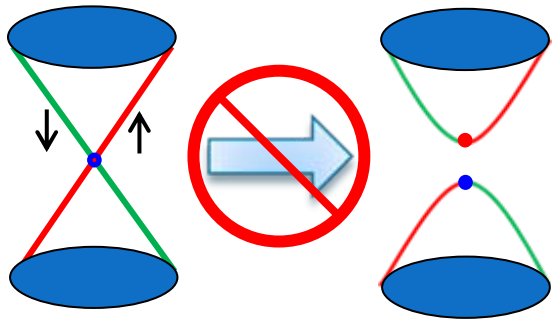


$$S = w \cdot t = 6.6 \times 10^{-15} \text{ m}^2$$

fully coverage of 2D coherent electron state on the entire surface

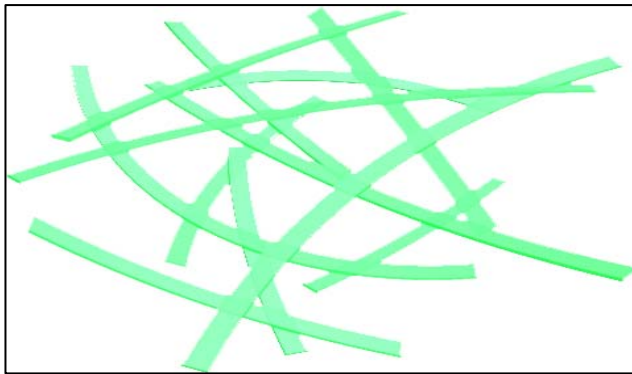
Topological Insulator 2D Nanostructures for Flexible Transparent Electrodes

Metallic surface state: robust, high mobility ($1000\sim 5000\text{ cm}^2/\text{Vs}$)

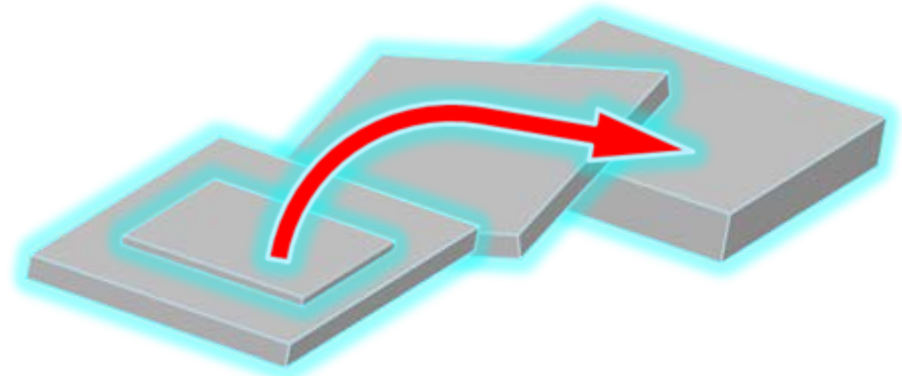


Metallic surface/edge state always occur at interface, boundary, edge

H. Peng, K. Lai, Y. Cui, et al., *Nature Materials* 9, 225 (2010).

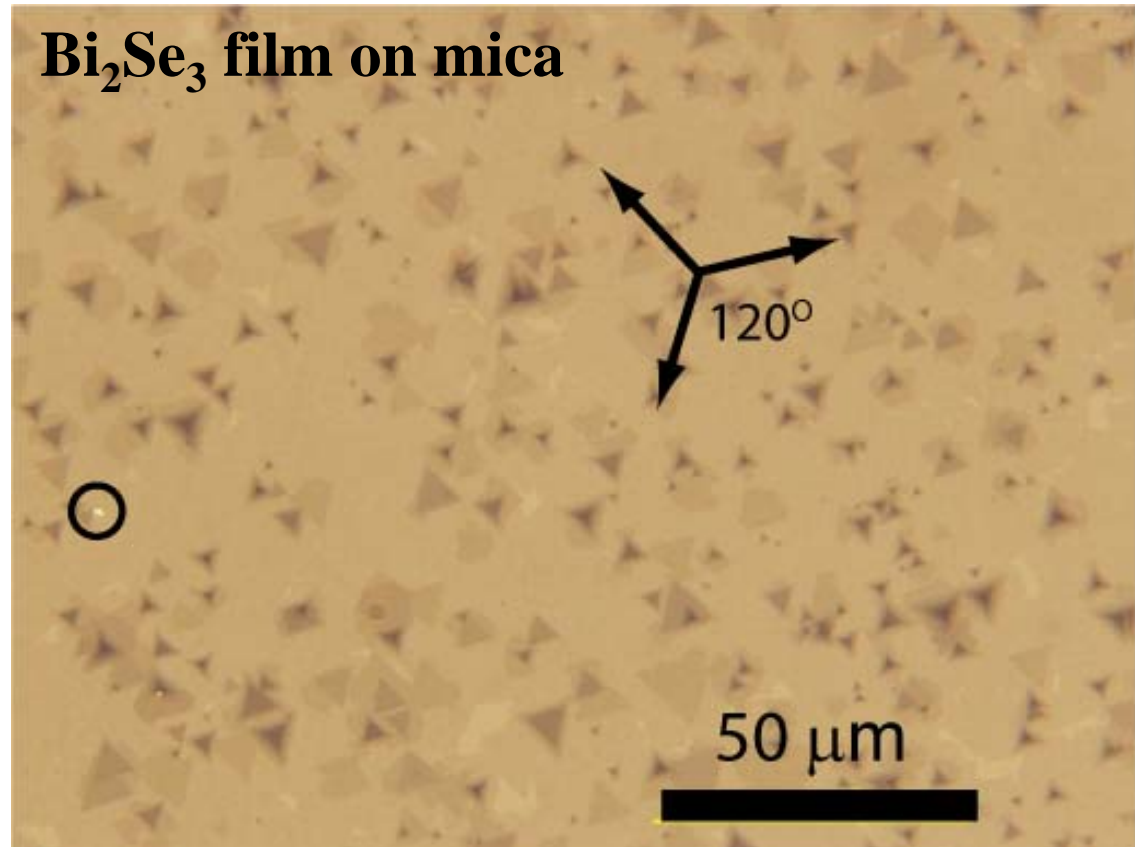
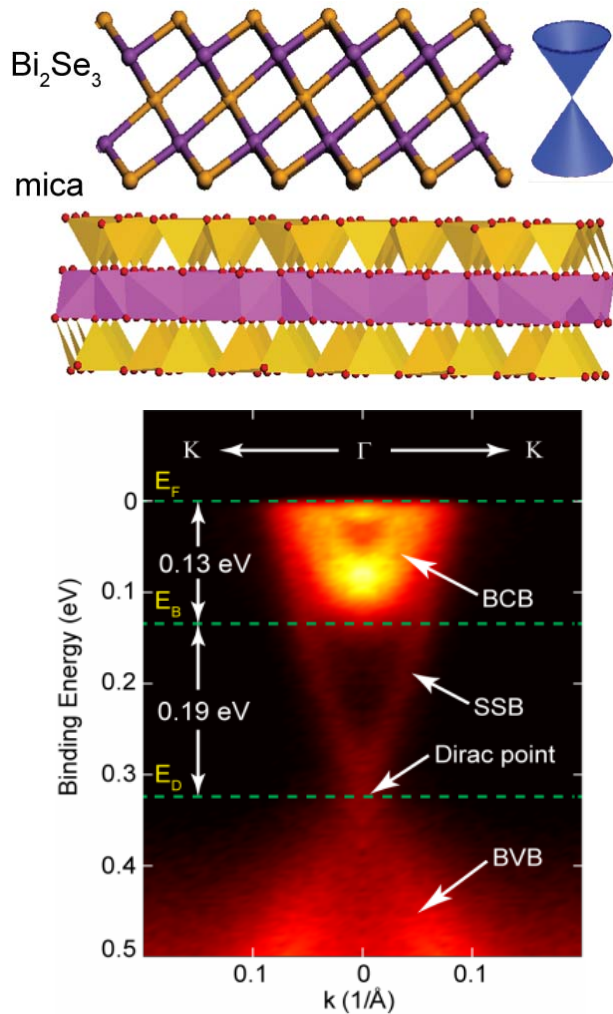


dissipationless interconnects for the conductive paths



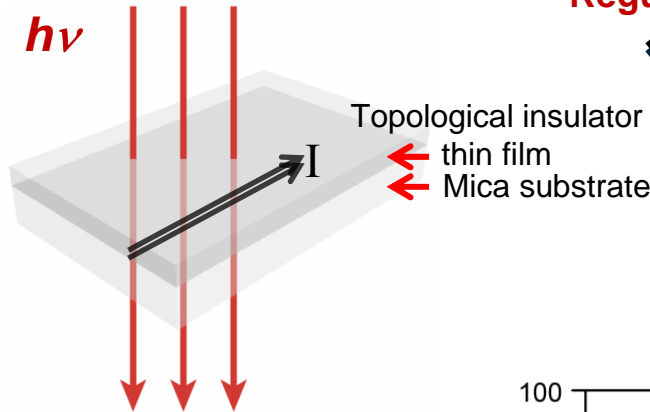
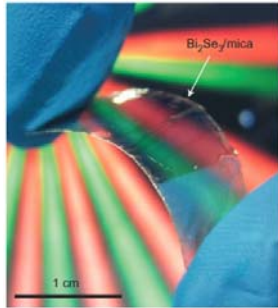
Transparent electrode
拓扑导电薄膜

Topological Insulator 2D Nanostructures for Flexible Transparent Electrodes

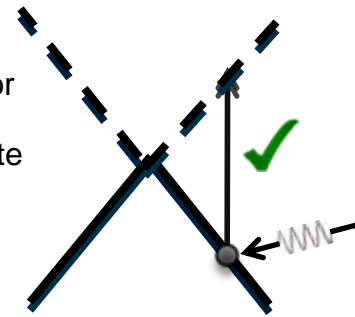


H. Peng*, et al., *Nature Chemistry* **4**, 281 (2012)
highlight in *Nature Chemistry*, *Nature Photonics*, *PhysOrg.com*, etc.

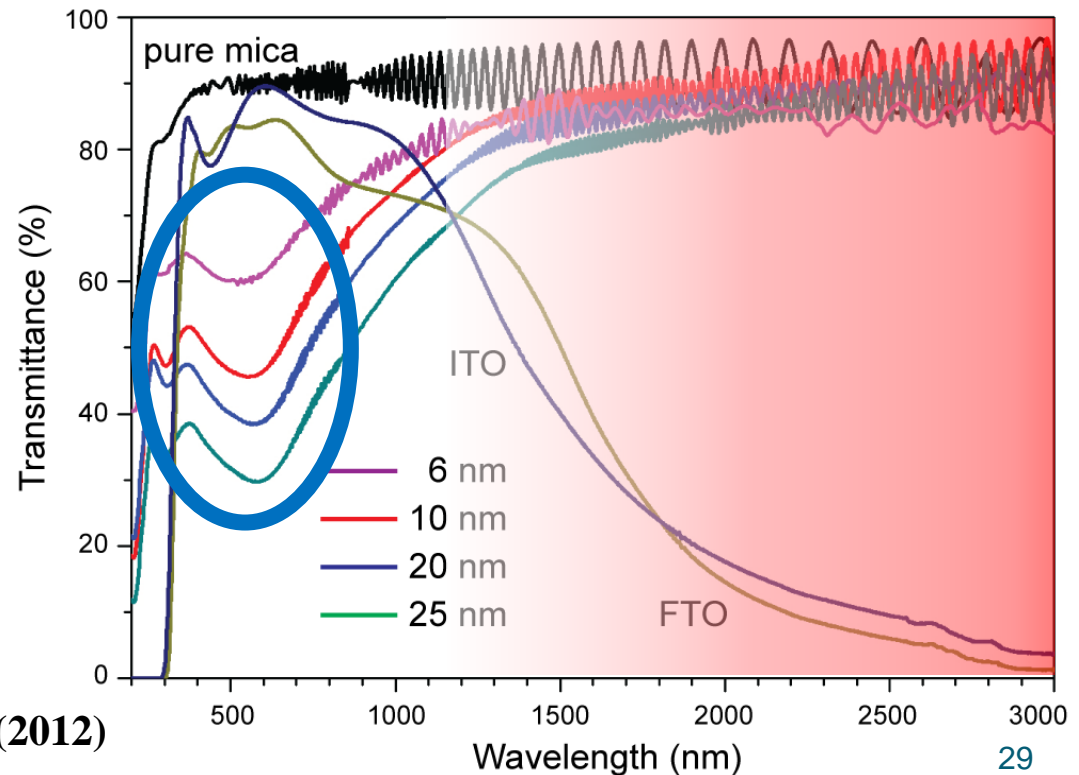
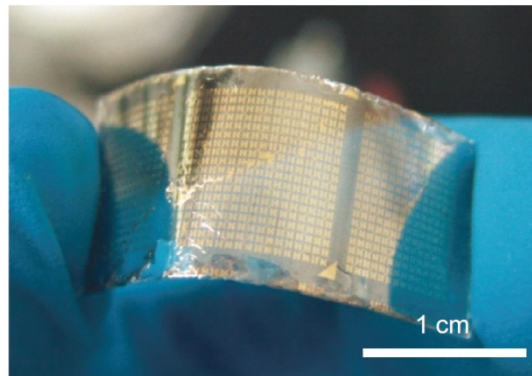
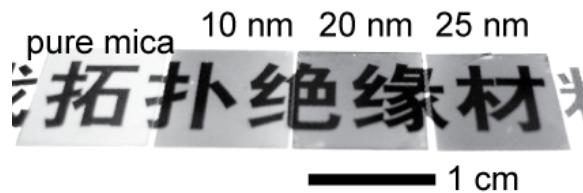
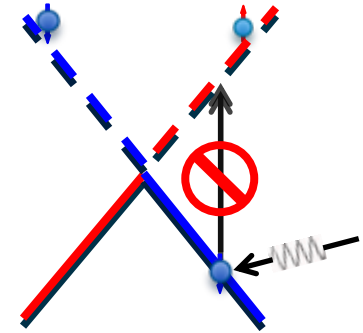
Transparent Electrodes - Transmittance



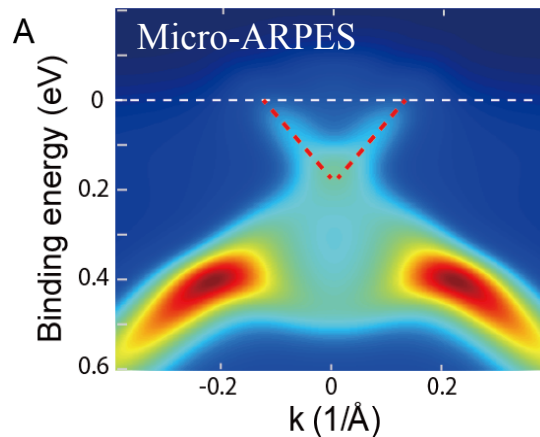
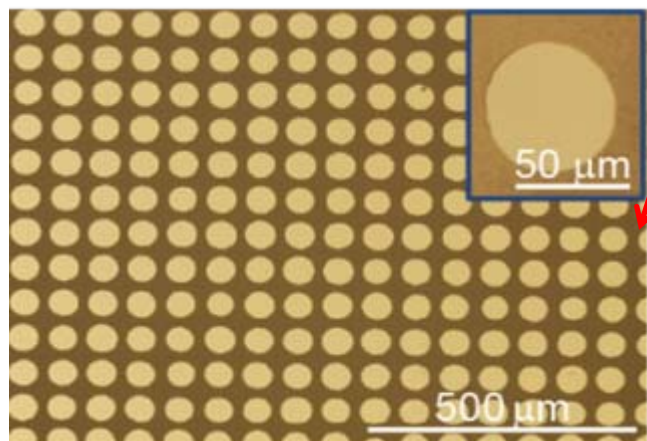
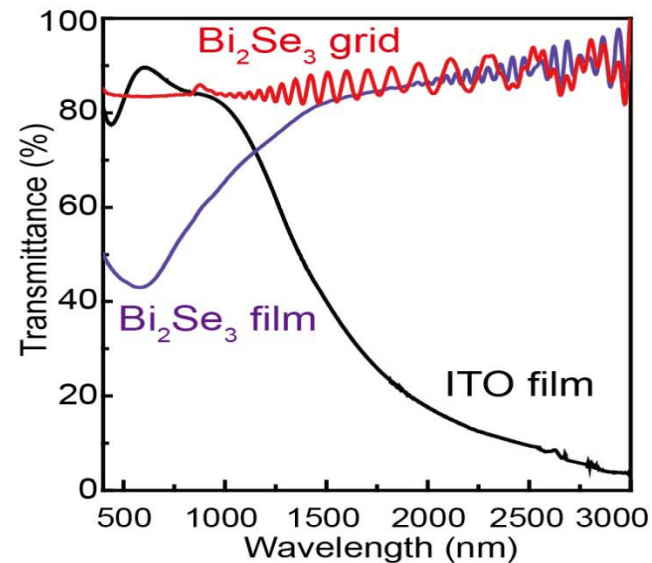
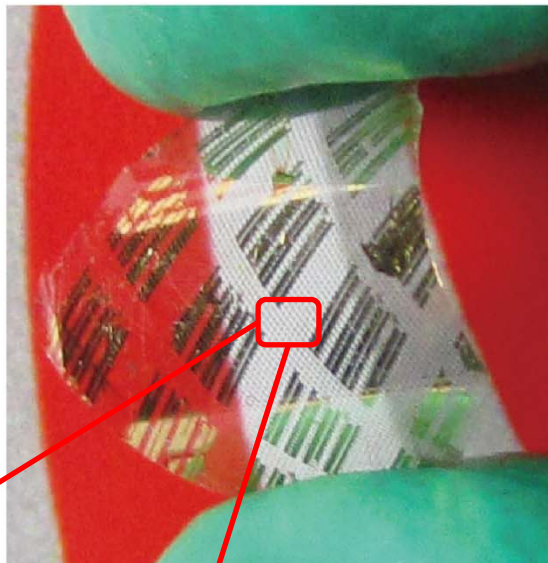
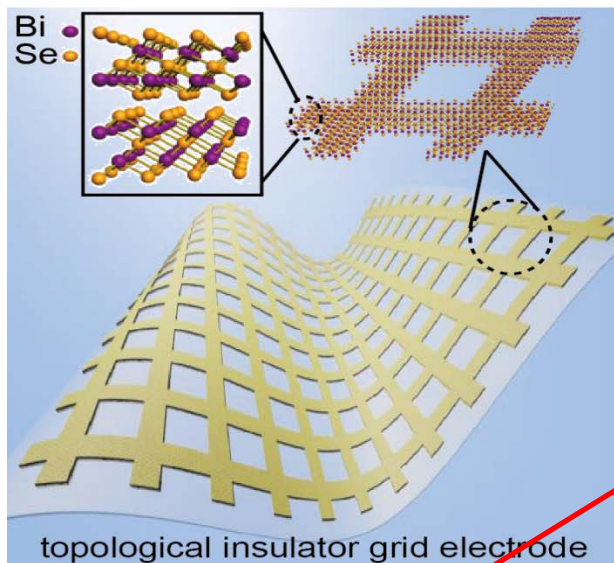
Regular Dirac fermion



Helical Dirac fermion in TI

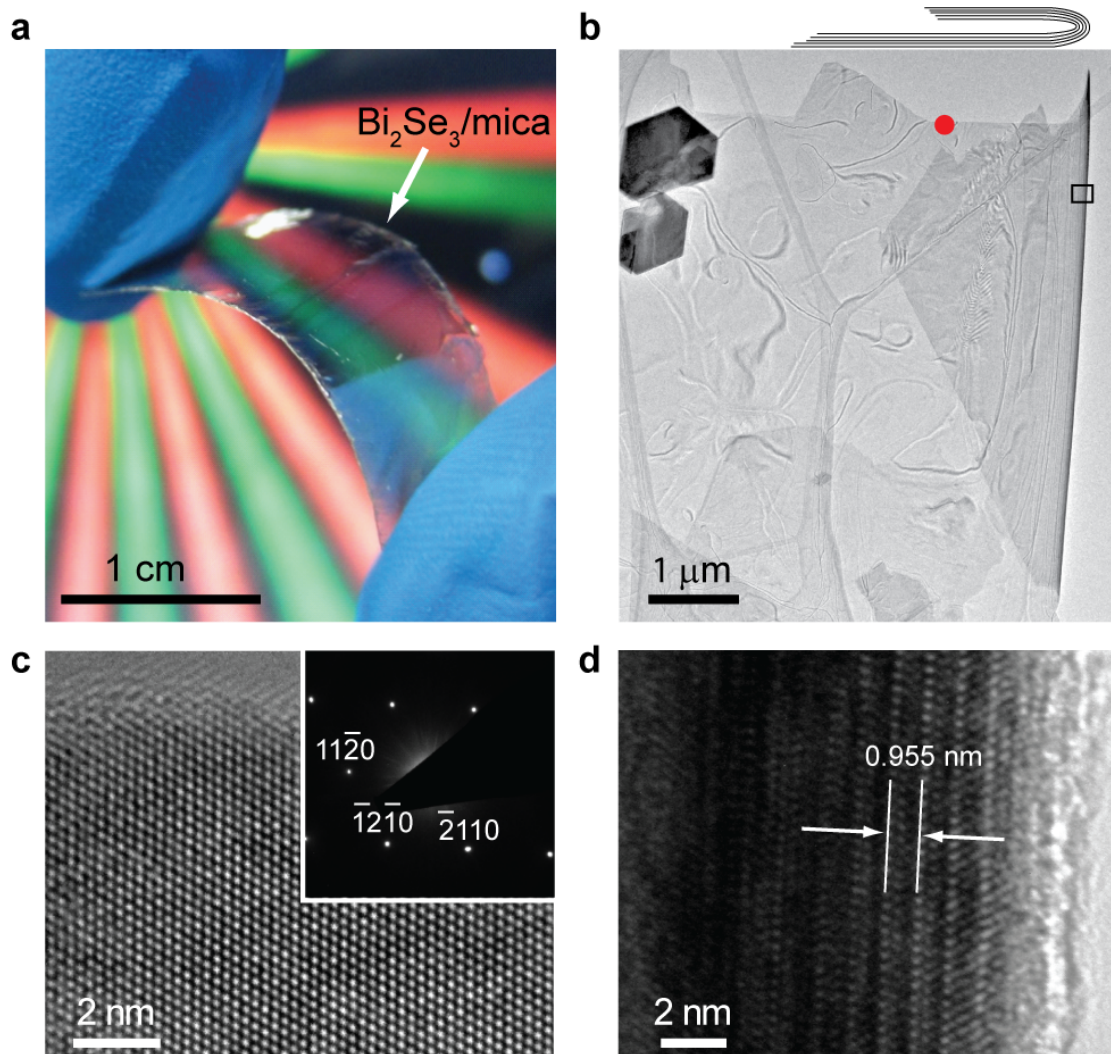


Broadband Transparent Electrodes with 2D Grid



Yunfan Guo, Hailin Peng*, et al., *Adv. Mater.* 2013, in press

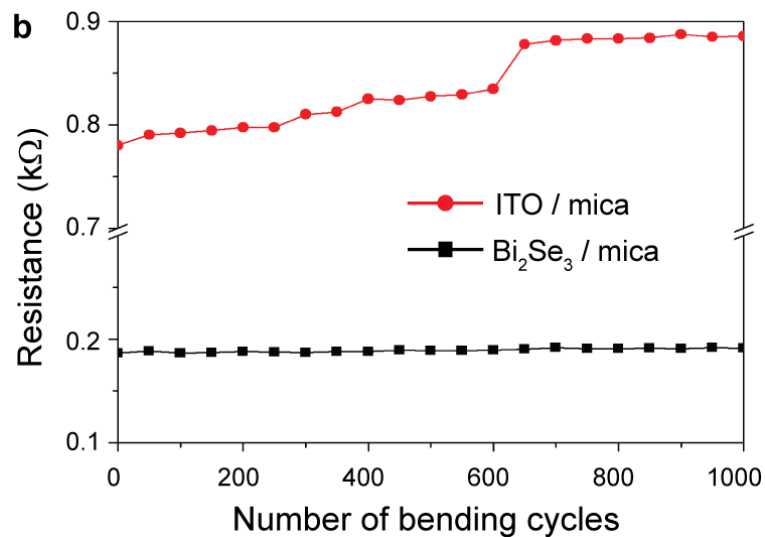
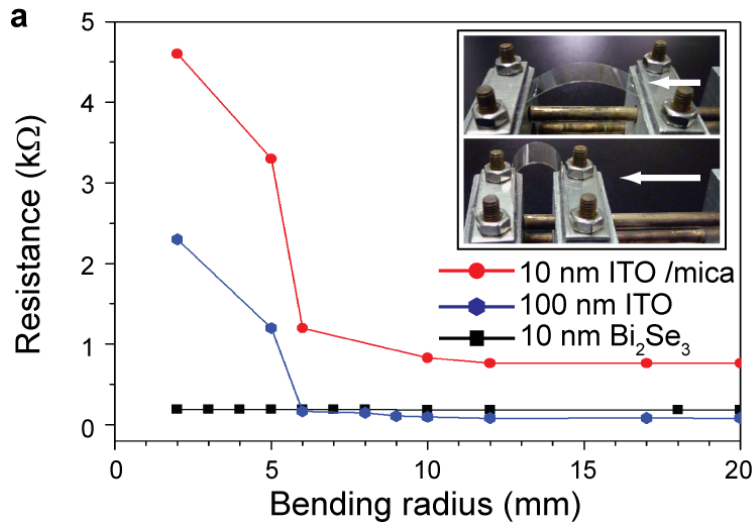
Transparent Electrodes - Flexibility



H Peng*, *et al.*, *Nature Chemistry* 4, 281 (2012)

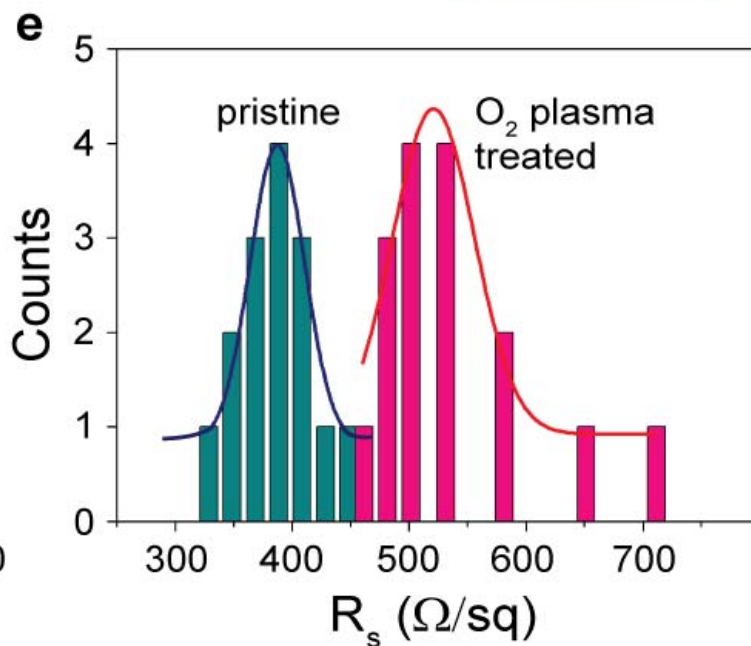
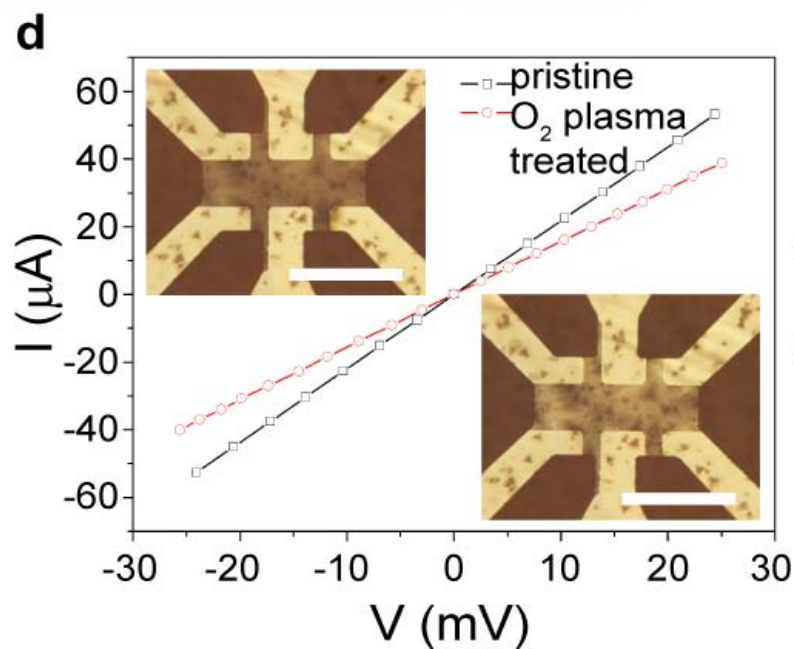
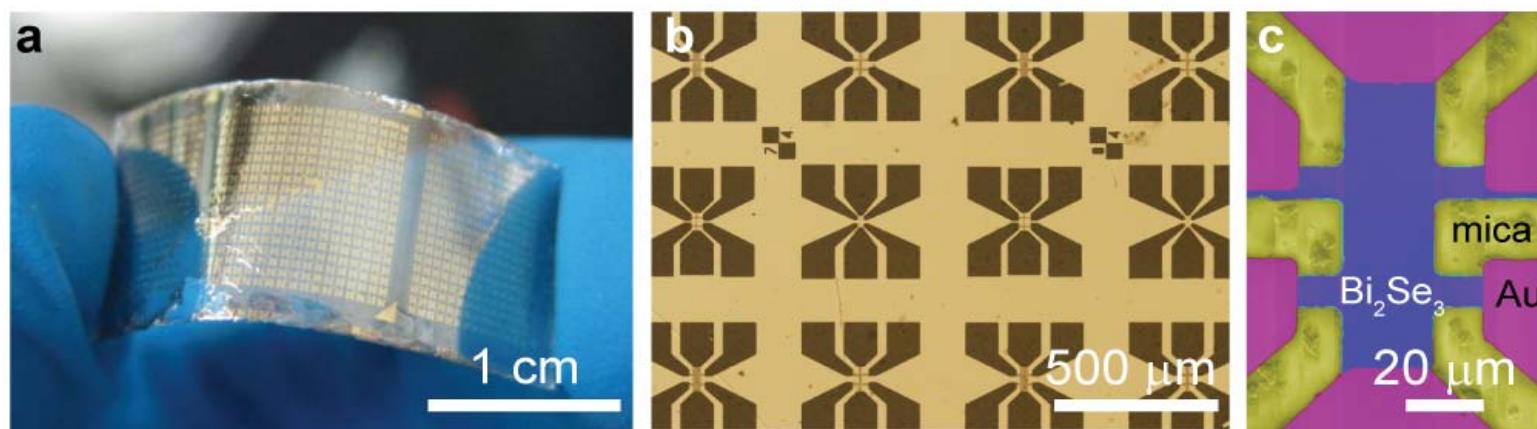
highlight in *Nature Chemistry*, *Nature Photonics*, *PhysOrg.com*, etc.

Transparent Electrodes - Flexibility



H Peng*, *et al.*, *Nature Chemistry* 4, 281 (2012)
highlight in *Nature Chemistry*, *Nature Photonics*,
PhysOrg.com, etc.

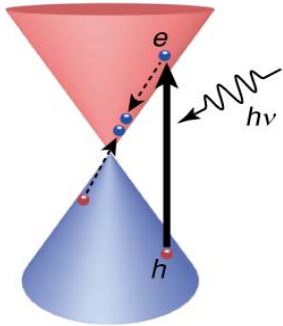
Transparent Electrodes – Robust Conduction



H. Peng*, et al., *Nature Chemistry* 2012, 4, 281

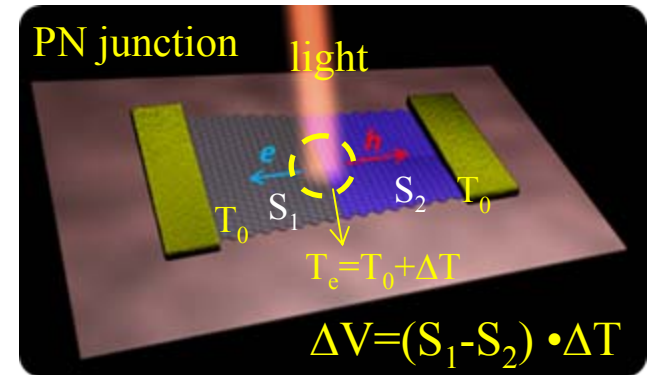
Optoelectronic properties of graphene p-n junction

The thinnest p-n junction



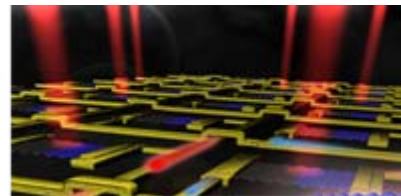
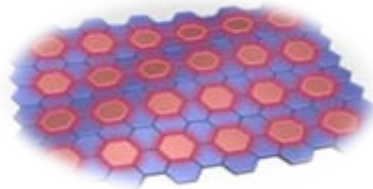
- ◆ Ultrahigh carrier mobility
- ◆ Broadband absorption
- ◆ Hot-carrier multiplication
- ◆ Weak electron-phonon coupling
- ◆ Tunable thermopower
- ◆ Photo-thermoelectric effect

Photo-thermoelectric effect



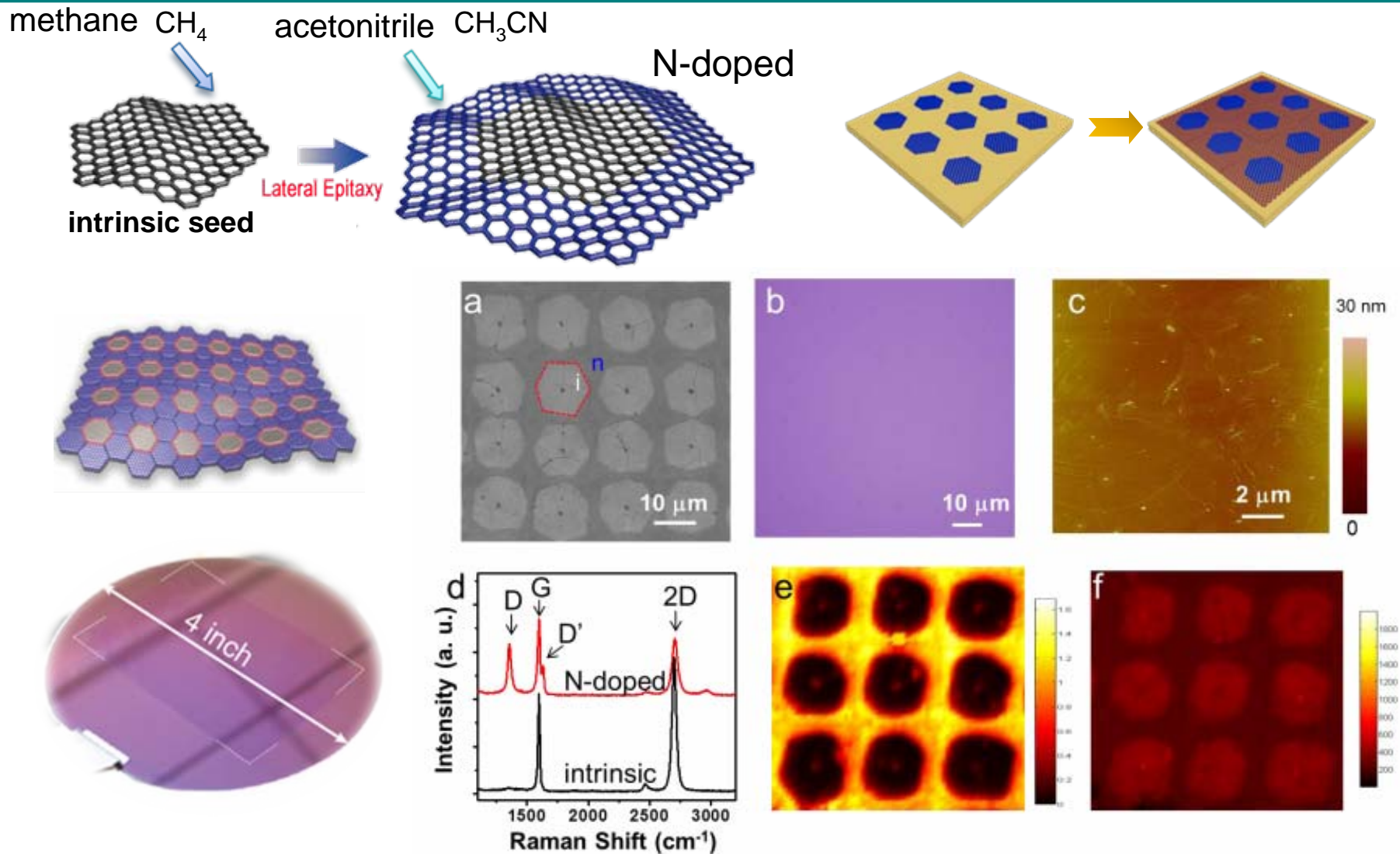
Potential applications in optoelectronic devices

- broadband and ultrafast photodetector
- high-efficiency photoelectric conversion



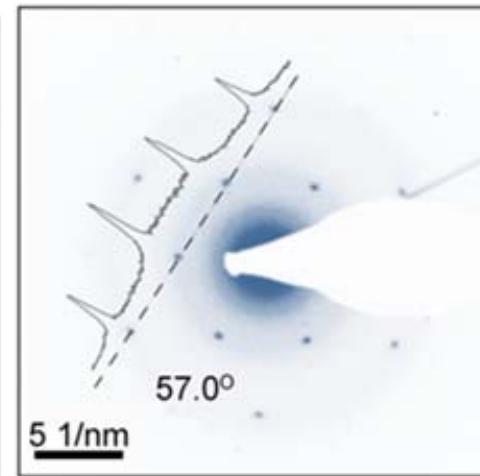
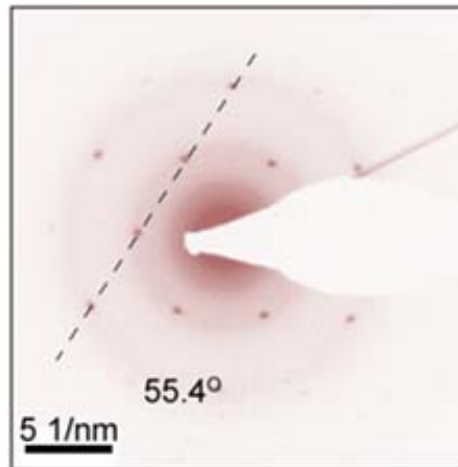
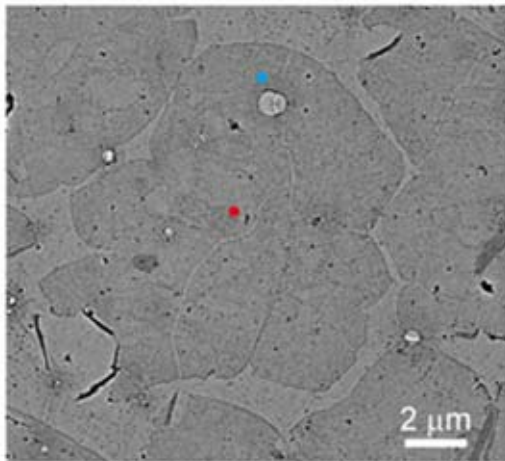
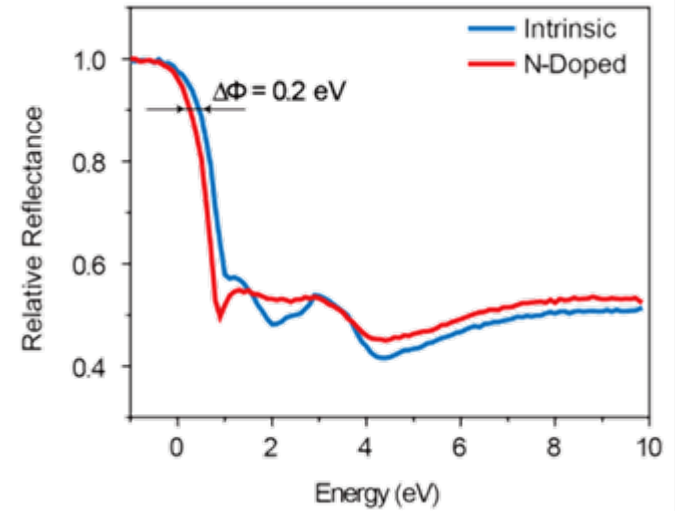
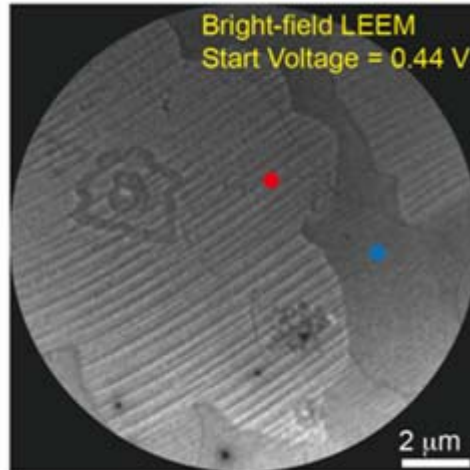
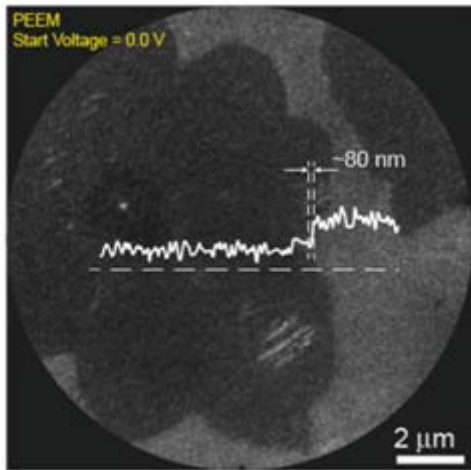
Synthesis of graphene p-n junction is challenging

Modulation-doped growth of mosaic graphene p-n junctions

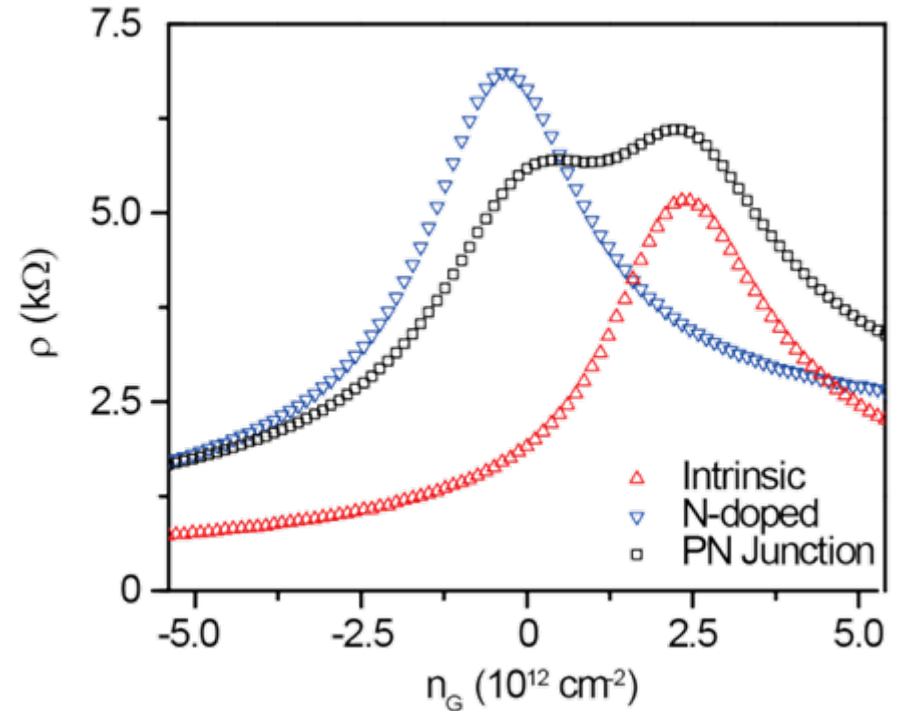
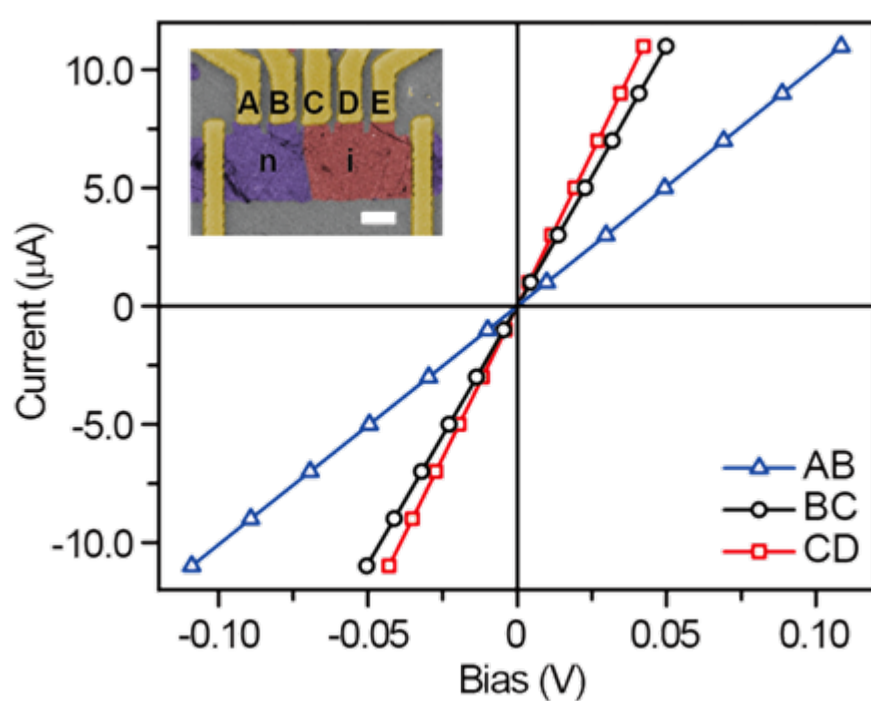


Yan, Wu, Peng*, Jin, Fu, Bao, Liu*, *Nature Communications* 2012, 3, 1280

Characterizations of mosaic graphene p-n junctions



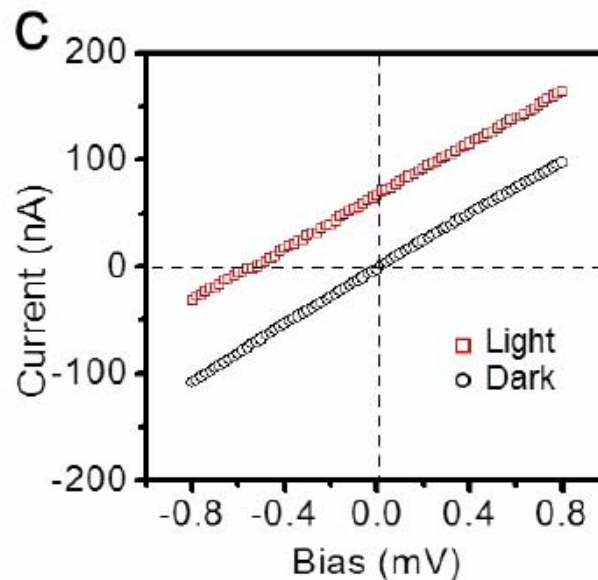
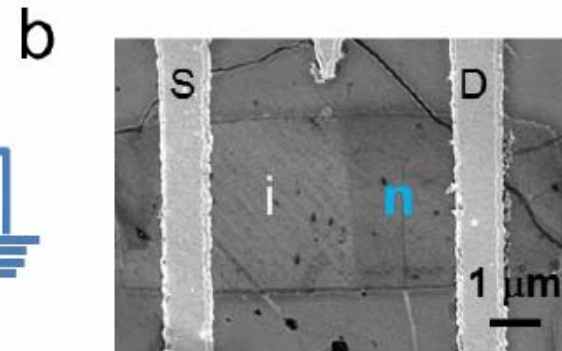
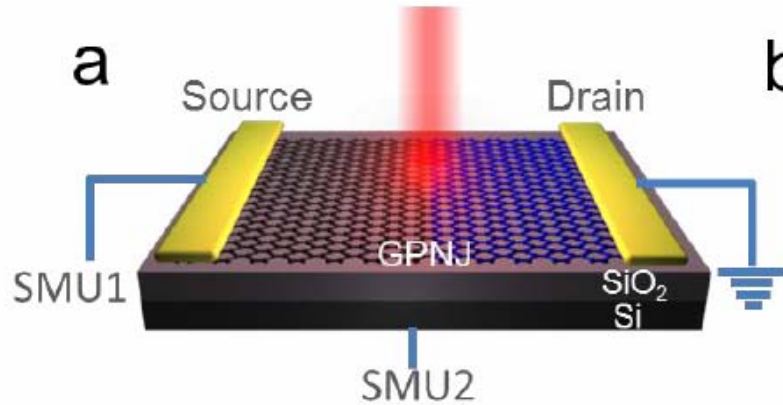
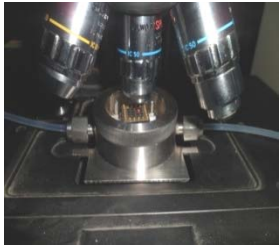
Transport of single crystal graphene p-n junction



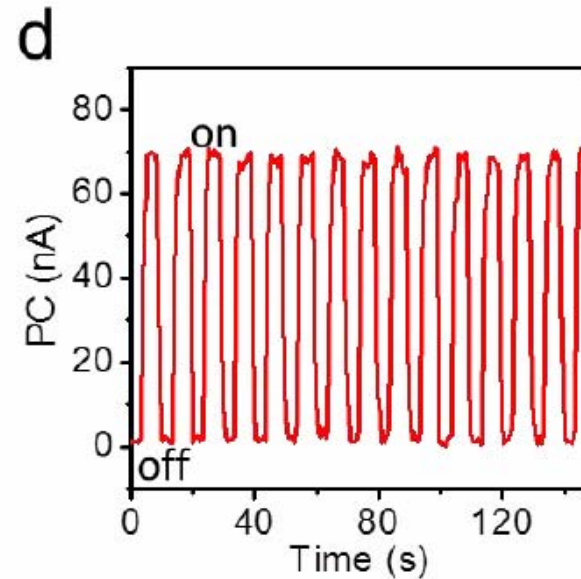
mobility of intrinsic graphene: $5000 \text{ cm}^2 \text{ V}^{-1} \text{ s}^{-1}$

mobility of N-doped graphene: $2500 \text{ cm}^2 \text{ V}^{-1} \text{ s}^{-1}$

Photocurrent generation of graphene p-n junction

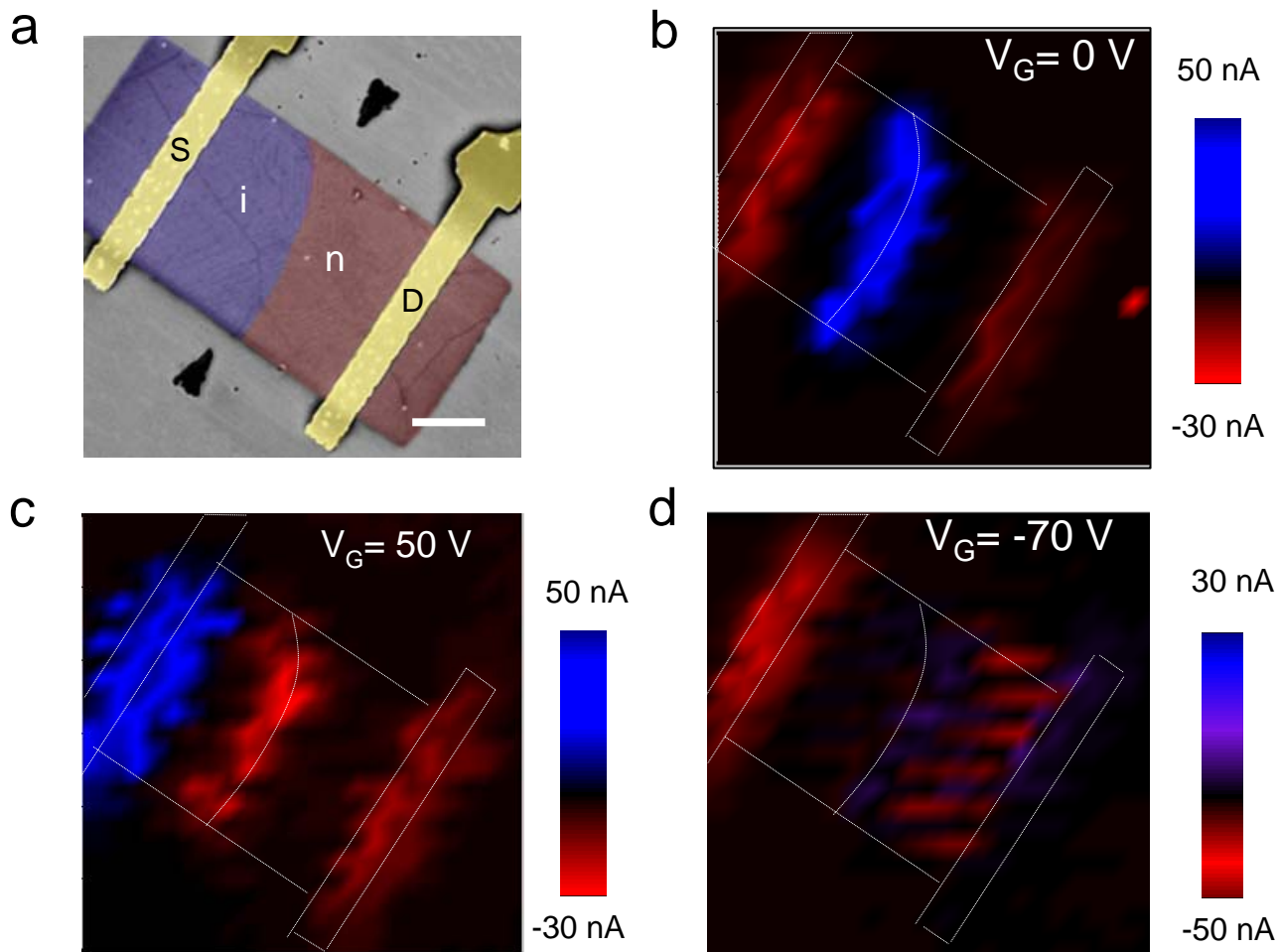


Photoresponse: $0.14 \text{ mA} \cdot \text{W}^{-1}$



Yan, Wu, Peng*, Jin, Fu, Bao, Liu*, *Nature Communications* 2012, 3, 1280

Photocurrent maps at different gate bias



Photoelectric measurement and transfer of p-n junction at different gate bias

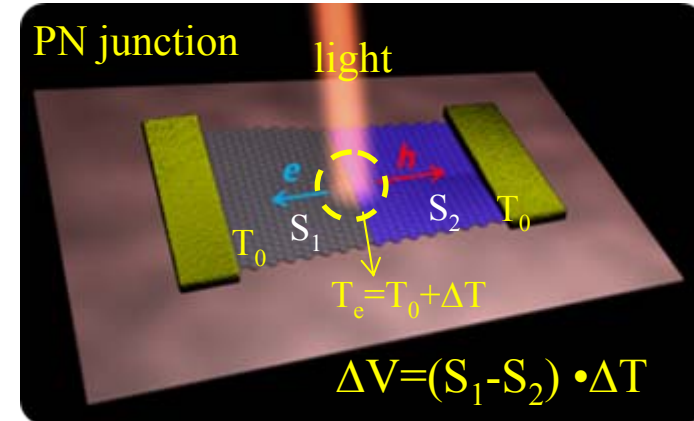
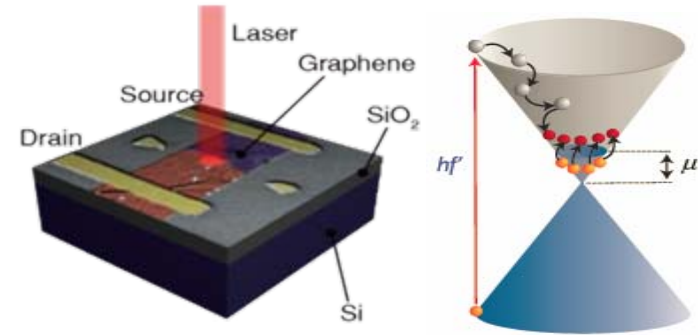
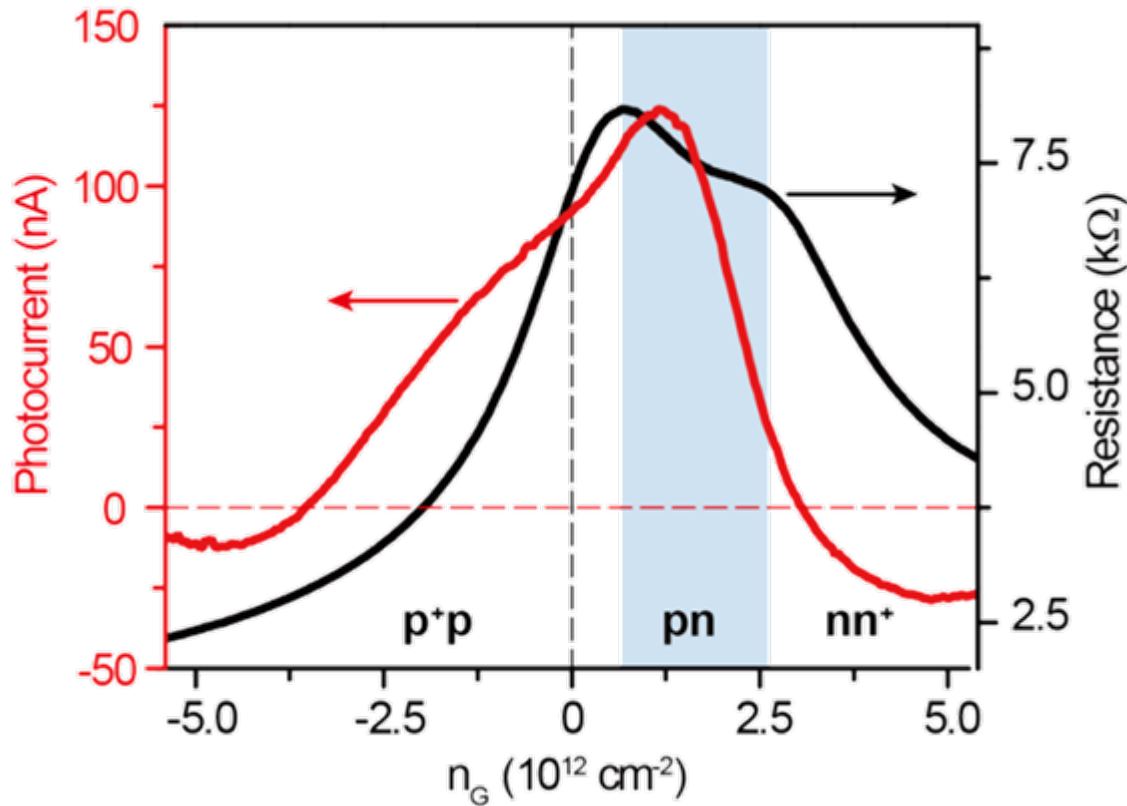
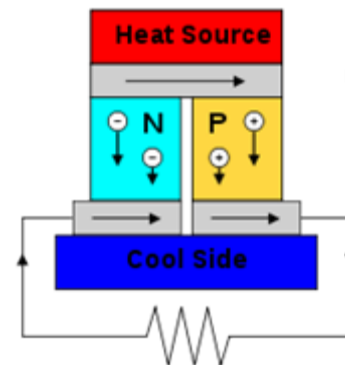


Photo-thermoelectric effect

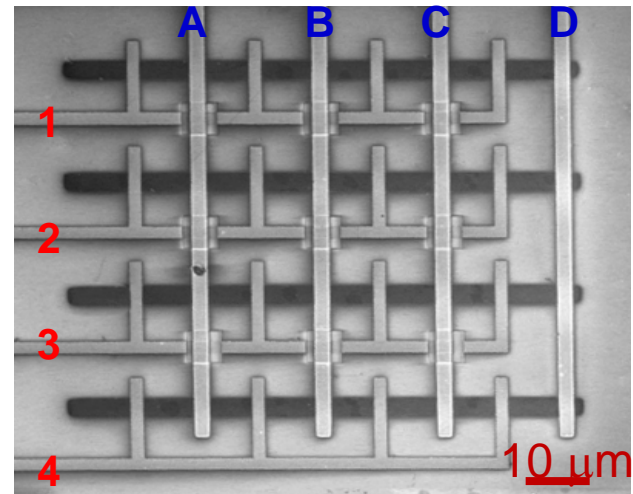
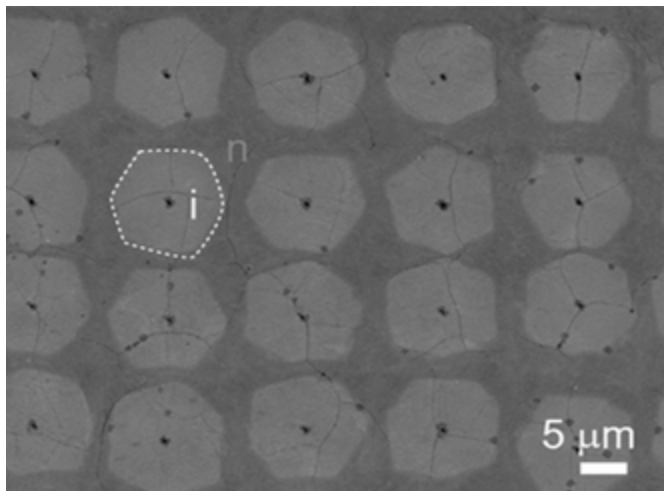
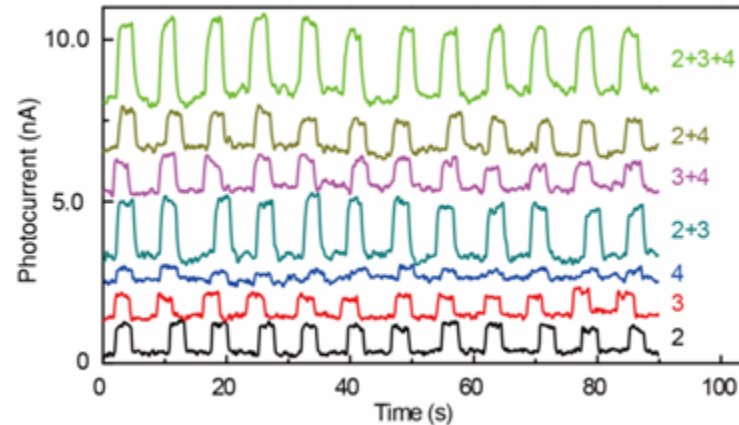
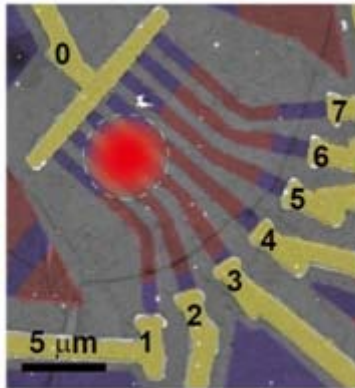
(See Pablo Jarillo-Herrero, *Science* 2011, 4, 648)



Yan, Wu, Peng*, Jin, Fu, Bao, Liu*, *Nature Communications* 2012, 3, 1280

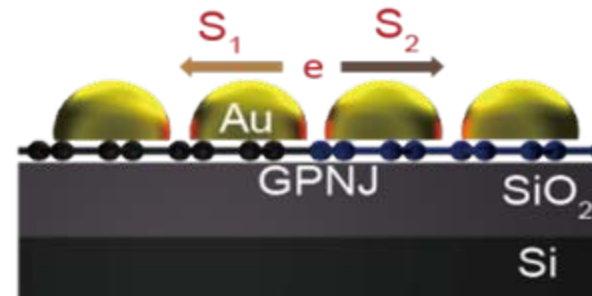
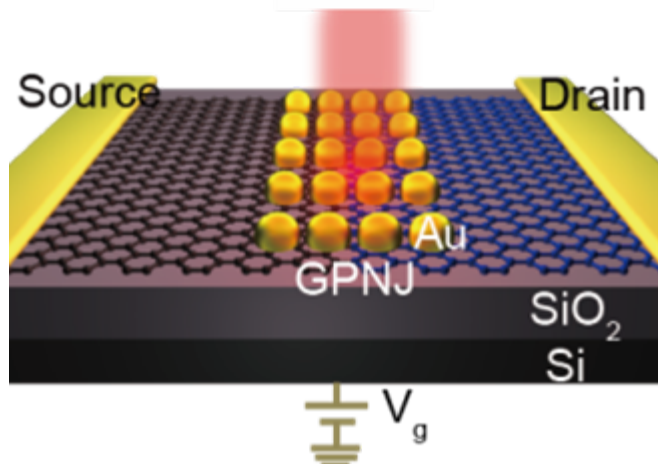
Photoresponses of individual channels and their additions

integration of multiple graphene photodetector channels

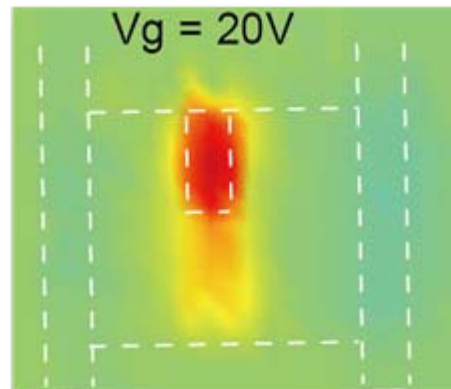
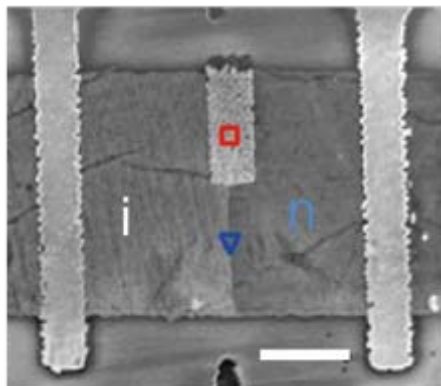


cooperative photodetection

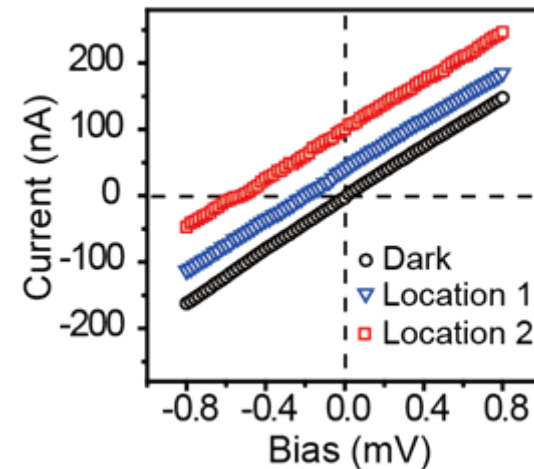
Plasmon enhanced photo-thermoelectric conversion at graphene p-n junction



Plasmon enhanced PTE conversion

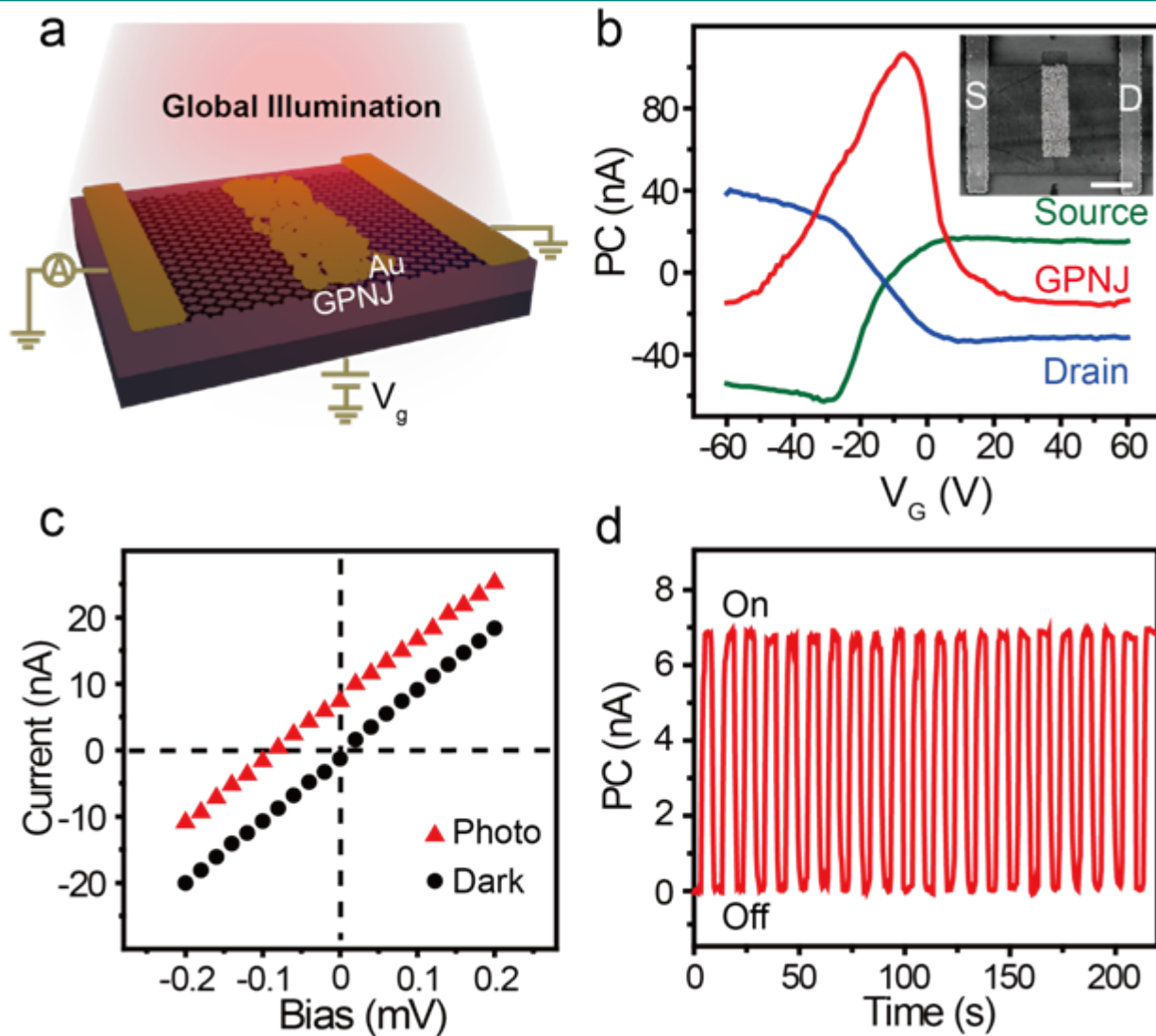


-120  120 nA



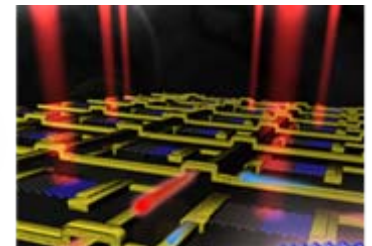
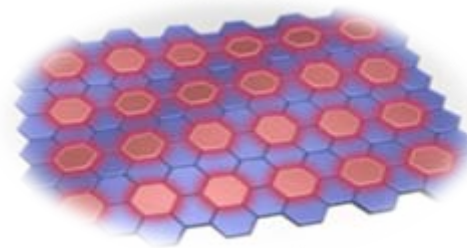
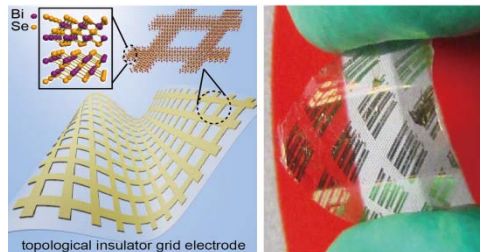
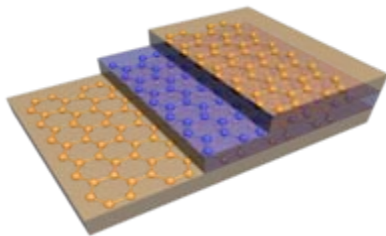
Enhancement factor: 4

Global light photodetection via plasmonic enhancement of photothermoelectric conversion



Summary

- 1. Material synthesis: vapor-liquid-solid, vapor-solid, and van der Waals epitaxy strategy** were employed for the growth of 2D crystals, including nanoplate array with controlled orientation, thickness, and placement.
- 2. Near-infrared transparent flexible electrodes** based on few-layer topological-insulator Bi_2Se_3 nanostructures was demonstrated for the first time. In addition, we present the realization of **broadband transparent electrodes** with 2D grids of topological insulator.
- 3. Modulation doped graphene** was grown via a large-scale CVD process. Pronounced photocurrent was observed in CVD hybrid graphene with p-n junctions.



Thank you for your attention

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